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# SERVICE MANUAL

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Icom Inc.

### INTRODUCTION

This service manual describes the latest service information for the **IC-R100** WIDEBAND RECEIVER at the time of going to press.

5 versions of the **IC-R100** have been designed. This service manual covers each version.

VERSION NO.	VERSION	SYMBOL
#2	U.S.A.	USA
#3	Europe	EUR
#4	Australia	AUS
#5	Germany	FRG
#6	France	FRA

To upgrade quality, all electrical or mechanical parts, and internal circuits are subject to change without notice or obligation.

### **DANGER**

**NEVER** connect the receiver to an AC outlet or to a DC power supply that uses more than 16 V. This will ruin the receiver.

**DO NOT** expose the receiver to rain, snow or any liquids.

**DO NOT** reverse the polarities of the power supply when connecting the receiver.

**DO NOT** apply an RF signal of more than 20 dBm (100 mW) to the antenna connector. This could damage the receiver's front end.



### **ORDERING PARTS**

Be sure to include the following four points when ordering replacement parts:

- 1. 10-digit order numbers
- 2. Component part number and name
- 3. Equipment model name and unit name
- 4. Quantity required

### <SAMPLE ORDER>

1130001000 IC μPD4066BC IC-R100 MAIN UNIT 5 pieces 8810006130 Screw BiH M2.6×5 IC-R100 Top cover 10 pieces

Addresses are provided on the inside back cover for your convenience.

### **REPAIR NOTE**

- 1. Make sure a problem is internal before disassembling the receiver.
- 2. **DO NOT** open the receiver until the receiver is disconnected from its power source.
- 3. **DO NOT** force any of the variable components. Turn them slowly and smoothly.
- DO NOT short any circuits or electronic parts.
   An insulated tuning tool MUST be used for all adjustments.
- 5. **DO NOT** keep power ON for a long time when the receiver is defective.
- 6. **READ** the instructions of test equipment thoroughly before connecting equipment to the receiver.

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### SECTION 1 SPECIFICATIONS

Frequency coverage

VERSION	FREQUENCY COVERAGE
U.S.A., Europe, Australia	0.1∼1856 MHz*
Germany	13.95~ 14.5 MHz, 28.0~ 29.7 MHz, 144.0 ~ 146.0 MHz, 430.0~440.0 MHz, 1240.0 ~1300.0 MHz
France	0.1~87.5 MHz, 108.0~1856 MHz*

\*Specifications guaranteed for 0.5~1800 MHz

• Mode : AM, FM, Wide FM (WFM)

Tuning step increments
 1, 5, 8, 10, 12.5, 20 or 25 kHz (100∼521.5 kHz and 1.630∼904.9995 MHz)

1, 5, 8, 9, 10, 12.5, 20 or 25 kHz (522~1629.5 kHz)

12.5, 20 or 25 kHz (905~1856 MHz)

Antenna impedance : 50 Ω (unbalanced)

• Power supply requirement : 13.8 V DC±15 % (negative ground)

Current drain (at 13.8 V DC)
 Less than 1.1 A

• Usable temperature range :  $-10 \,^{\circ}\text{C} \sim +60 \,^{\circ}\text{C} (+14 \,^{\circ}\text{F} \sim +140 \,^{\circ}\text{F})$ 

• Frequency stability (at 1800 MHz):  $\pm 3.5$  ppm (0 °C $\sim +50$  °C;  $\pm 32$  °F $\sim +122$  °F)

• Number of memory channels : Memory channels 100

Priority channel 1 Scan edge channels 20 (for 10 scan ranges)

• Dimensions : 150 (W) × 50 (H) × 181 (D) mm

5.9 (W)  $\times$  2.0 (H)  $\times$  7.1 (D) in (Projections not included)

• Weight : 1.4 kg (3.1 lb)

Sensitivity

F	Sensitivity				
Frequency	FM	Wide FM	AM		
0.5 ~ 1.6295 MHz	_	_	3.2 μV		
1.63∼ 49.9995 MHz	0.56 μV	_	1.6 μV		
50.0 ∼ 904.9995 MHz	0.2 μV	0.63 μV	0.56 μV		
905.0 ~1380.4875 MHz	0.32 μV	0.79 μV	1.0 μV		
1380.5 ~1800.0 MHz	0.45 μV	1.1 μV	1.4 μV		

Measurement conditions:

Preamp is ON in the  $50\sim904.9995$  MHz frequency range. FM 12 dB SINAD (1 kHz modulation with  $\pm3.5$  kHz deviation) WFM 12 dB SINAD (1 kHz modulation with  $\pm50$  kHz deviation)

AM 10 dB S/N (1 kHz modulation with 30 % depth)

• Selectivity : FM More than 15 kHz/-6 dB

WFM More than 180 kHz/-3 dB AM More than 6 kHz/-6 dB

• Audio output power : More than 2.5 W at 10 % distortion with an 8  $\Omega$  load.

Audio output impedance : 4~8 Ω

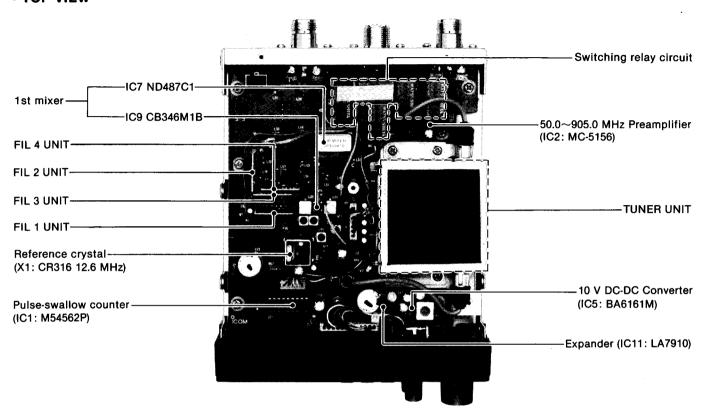
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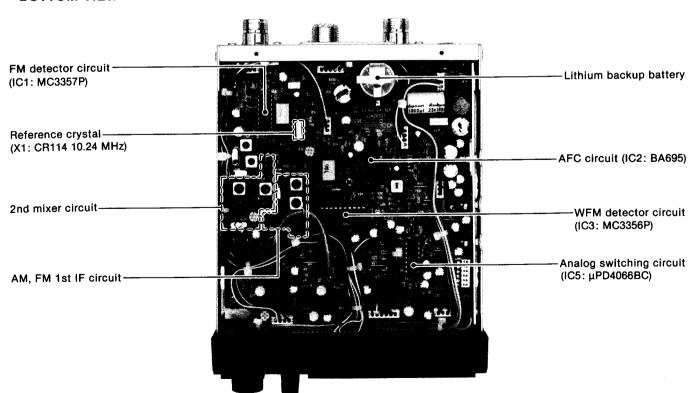
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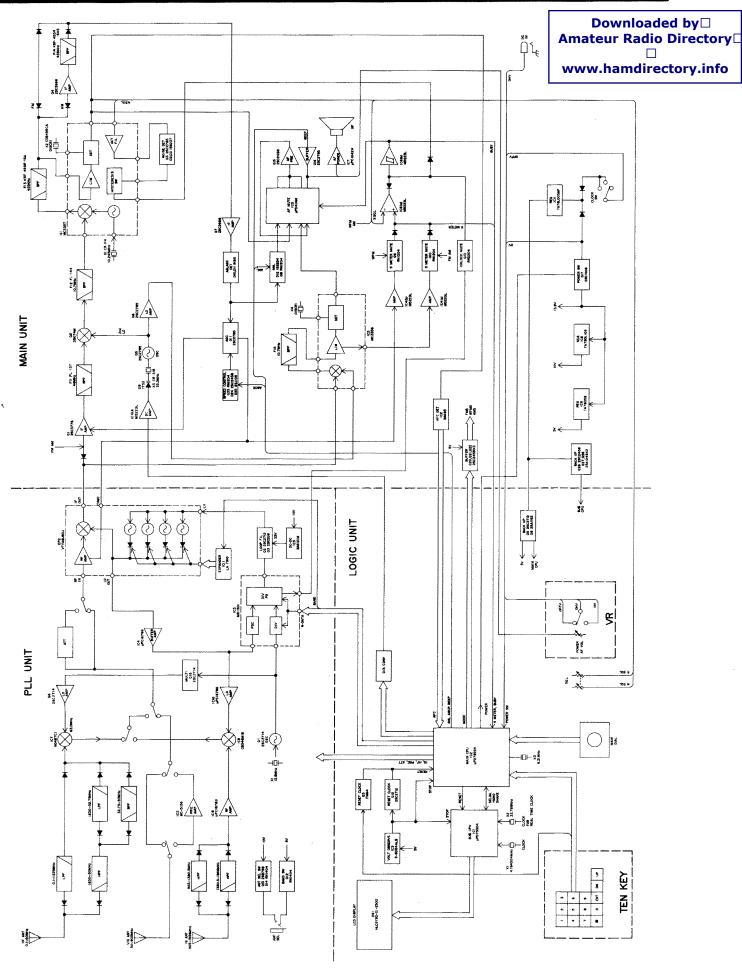
# SECTION 2 INSIDE VIEWS

### • TOP VIEW



### BOTTOM VIEW





### SECTION 4 CIRCUIT DESCRIPTION

### 4-1 RF CIRCUITS

### 4-1-1 FILTER CIRCUIT (PLL UNIT)

The IC-R100 has 3 antenna connectors (J7, J8, J9) for a super-wideband receiving range of 0.1 MHz to 1856.0 MHz. Received signals enter one of the 3 antenna connectors depending on the receive frequency range.

### (1) 0.1~50.0 MHz FILTER

RF signals from an antenna connector (J8) are distributed to three separate filters through switching diodes (D10, D12) for filter selection.

### • 0.1000~1.6290 MHz

After passing through a switching diode (D10), a 0.1000~1.6290 MHz signal is applied to an attenuator consisting of R64~R66. The attenuator prevents distortion of very strong signals from medium wave broadcasting stations. The signal is applied to FIL 1 (C1~C5, L1, L2) which forms a low-pass filter. The filter circuit cuts off frequencies of 1.6290 MHz or higher. The filtered signal passes through a switching diode (D11).

### • 1.6295~32.7495 MHz

After passing through a switching diode (D12), a  $1.6295\sim32.7495\,\text{MHz}$  signal is applied to FIL 2 (C1 $\sim$ C7, L1, L2) which forms a high-pass filter. The filter circuit passes frequencies approx. 1.630 MHz or lower. The signal is applied to FIL 3 (C1 $\sim$ 5, L1, L2) which forms a low-pass filter. The filter circuit cuts off approx. 32.75 MHz or higher. The filtered signal passes through a switching diode (D14).

### • 32.7500~49.9995 MHz

A 32.7500 MHz~49.9995 MHz signal is applied to FIL 2 through the switching diode (D12). The signal is applied to FIL 4 (C1~C9, L1~L4) which forms a bandpass filter. The bandpass filter passes signal within the frequency range of 32.7500~50.0000 MHz. The filtered signal is applied to the switching diode (D14).

### • RF CIRCUITS

# 0.1—49.9995 MHz 0.1—1.6290 MHz FIL 1 FIL 2 HPF 1.6295—49.9995 MHz FIL 3 LPP 1.6295—49.9995 MHz LO signal from IC10

### (2) 50.0~905.0 MHz FILTER

No filter is installed in this frequency range. RF signals enter an antenna connector (J7) and then are applied to the RF relay circuit (RL2, RL3). The RF relay circuit switches the signals to bypass through a preamplifier (IC2) or be amplified at the preamplifier. The preamplifier (IC2) provides 15 dB gain to attenuate an IF signal level at an attenuator circuit (Q16) when the preamplifier circuit is turned ON.

### (3) 905.0~1856.0 MHz FILTER

RF signals enter an antenna connector (J9) and then pass through a switching diode (D18). The signals are applied to two separate high-pass filters for frequencies lower than and higher than 1380.5 MHz. The filtered signals pass through a switching diode (D21).

# 4-1-2 HF BAND CONVERTER CIRCUIT (PLL UNIT)

The filtered signals entering at J8 are applied to a 1st mixer circuit consisting of IC7, L29, L30 and then are mixed with a 63.0 MHz 1st LO signal to produce a 63.1  $\sim$ 112.9995 MHz 1st IF signal corresponding to the receive frequency range of 0.1 $\sim$ 49.9995 MHz.

The 63.0 MHz 1st LO signal is generated by a local oscillator (X1, Q1). X1 produces a 12.6 MHz reference frequency. The reference frequency is multiplied by five at LO amplifiers (Q6, Q15) for producing the 63.0 MHz 1st LO signal.

# 4-1-3 1GHz BAND CONVERTER CIRCUIT (PLL UNIT)

The filtered signals entering at J9 are applied to a RF amplifier (IC8) corresponding to a UHF band and then applied to a 1st mixer circuit (IC9). IC9 is a DBM (Double Balanced Mixer). The signals are mixed with a 475.5  $\sim\!905.0\,\mathrm{MHz}$  1st LO signal to produce a 429.5  $\sim\!905.0\,\mathrm{MHz}$  1st IF signal corresponding to the receive frequency range of  $905.0\,\sim\!1856.0\,\mathrm{MHz}$ . The 475.5  $\sim\!905.0\,\mathrm{MHz}$  1st Lo signal is buffer-amplified at IC10 depending on the receive frequencies. The signal is applied to the 1st mixer circuit (IC9).

### 4-2 IF CIRCUITS

### 4-2-1 TUNER UNIT (PLL UNIT)

The TUNER UNIT (EP2) contains an RF amplifier controlled by the TAGC signal, mixer and 4 VCOs. The RF signals are applied to P2 on the TUNER UNIT (EP2) to be converted to a 46 MHz IF signal. The TUNER UNIT (EP2) outputs the signal from pin 8. IC2 on the LOGIC UNIT supplies 2-bit data to IC11 (pin 3, 4). IC11 is an expander for switching the operating band of TUNER UNIT (EP2). The following table (Fig 2) shows the relations between 2-bit data and the band signal.

FREQUENCY RANGE	Ī	J1 (PLL UNIT) OUTPUT DATA			**	IC11 (PLL UNIT)				
(MHz)	BS0	B\$1	BS2	HF	1G	1GF	B1	B2	В3	B4
0.100 ~ 1.6290				Н			Н			,
1.6295~ 32.7495				Н						
32.750 ~ 49.9995		Н		Н				Н		
50.000 ~ 95.7495							Н			
95.750 ~ 221.7495		Н						Н		
221.750 ~ 475.7495			Н						Н	
475.750 ~ 904.9995		Н	Н					[		
905.000 ~ 997.4875			Н		Н					н
997.500 ~1380.4875		Н	Н		Н					, ,
1380.500 ~1856.0000		Н	Н		н	Н				

H: High level

No indication: Low level

Fig. 2

### 4-2-2 AM/FM IF AND 2ND MIXER CIRCUITS (MAIN UNIT)

The 46 MHz IF signal passes through a switching diode (D1) with AM 5 and FM 5 signals when AM or FM mode is selected. The signal is applied to an IF amplifier and then applied to a crystal filter (FI1) to improve the selectivity.

The filtered signal is applied to a 2nd mixer (Q2) and then mixed with the 35.3 MHz 2nd LO signal to produce a 10.7 MHz 2nd IF signal.

A 35.3 MHz 2nd LO signal is generated by a 2nd local oscillator circuit consisting of D8, X3, Q5, and other components. The 2nd LO oscillator circuit produces a frequency step less than the PLL reference frequency.

The LOGIC UNIT supplies D/A converted signals to IC10 (pin 3) which correspond to each tuning step. The signals are amplified at IC10 and then applied to a varactor diode (D8) which shifts the oscillation frequency.

### AM/FM IF AND 2ND MIXER CIRCUITS

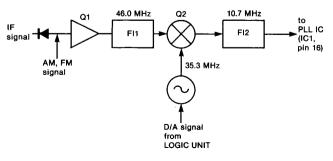


Fig. 3

### 4-2-3 2ND IF AND FM DEMODULATOR **CIRCUITS (MAIN UNIT)**

The 10.7 MHz 2nd IF signal is applied to FI2. FI2 is a MCF (Monolithic Crystal Filter) which suppresses out-ofband signals.

The 2nd IF signal is applied to a 3rd mixer section of IC1 and is mixed with a 3rd LO signal to be converted to a 455 kHz 3rd IF signal.

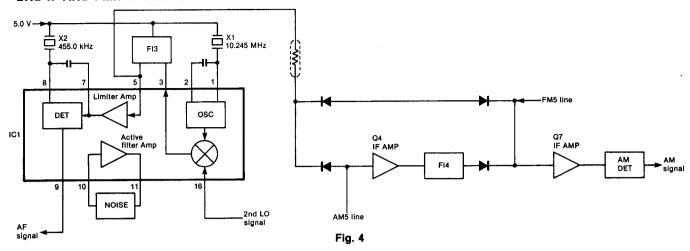
IC1 is designed for use in FM dual conversion communications equipment. IC1 contains the 3rd mixer, local oscillator circuit, limiter amplifier, quadrature detector circuit, and active filter circuit. The local oscillator section and X1 generate 10.245 MHz for a 3rd LO signal.

The 3rd IF signal from the 3rd mixer (IC1, pin 3) passes through a ceramic filter (FI3) where unwanted signals are suppressed. It is then amplified at the limiter amplifier section (IC1, pin 5) and applied to the quadrature detector section (IC1, pin 8 and ceramic discriminator X2) to demodulate the 3rd IF signal into an AF signal. The AF signal is output from IC1 (pin 9).

### 4-2-4 AM DEMODULATOR CIRCUIT (MAIN UNIT)

A portion of the 455 kHz 3rd IF signal is applied to an IF amplifier (Q4) after passing through the ceramic filter (FI3) when AM mode is selected by switching diodes (D5, D7). When the switching diodes are turned ON, AM 5 signal line obtains 5 V. The amplified signal passes through a ceramic filter (FI4) to improve selectivity. The filtered signal is re-amplified at an IF amplifier (Q7) and then rectified by the AM detector circuit (D10, D11). The 4 — 2 detected signal is demodulated into an AM signal.

### 2ND IF AND FM/AM DEMODULATOR CIRCUITS



# 4-2-5 WFM DEMODULATOR CIRCUIT (MAIN UNIT)

The 46 MHz IF signal is applied to a 2nd mixer section of IC3 and then mixed with the 35.3 MHz 2nd LO signal to produce a 10.7 MHz 2nd IF signal.

The 35.3 MHz 2nd LO signal is amplified at an LO amplifier (Q6) and is then applied to the 2nd mixer section through IC3 (pin 3).

IC3 is designed for use in digital data communications equipment. IC3 contains the 2nd mixer, local oscillator circuit, limiter amplifier and quadrature detector circuit.

The 2nd IF signal from the 2nd mixer (IC3, pin 5) passes through a ceramic filter (FI5) where unwanted signals are suppressed. It is then amplified at the limiter amplifier section (IC3, pin 7) and applied to the quadrature detector section (IC3, pin 11 and ceramic discriminator X4) to demodulate the 2nd IF signal into an AF signal. The AF signal is output from IC 3 (pin 13).

### 4-2-6 S-METER CIRCUIT (MAIN UNIT)

In WFM mode, the S-meter signal is output from IC3 (pin 14) and then applied to IC4(a) (pin 3). The amplified signal is applied to a main CPU (IC2, pin 93).

When the "WFM 5" line becomes "HIGH", the S-meter switch (Q9) is turned ON to cut off the FM or AM signal.

In FM or AM mode, the S-meter signal is applied to IC4(b) (pin 6) through the TAGC signal line. The inverted and amplified signal is applied to the main CPU (IC2, pin 93).

When the "FM 5" or "AM 5" line becomes "HIGH", the S-meter switch (Q10) is turned ON to cut off the WFM S-meter signal.

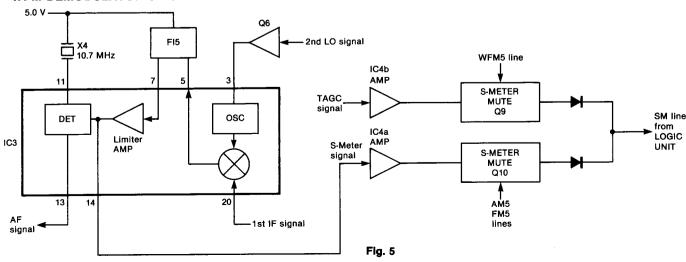
### 4-2-7 AGC CIRCUIT (MAIN UNIT)

In FM or AM mode, the signal is detected to obtain AGC voltage at D10 and D11 and is then amplified at an AGC amplifier (Q11). The amplified signal is distributed to a base of the IF amplifier (Q1) on the MAIN UNIT and the RF amplifier on the TUNER UNIT (EP2) through the TAGC line.

In WFM mode, the "WFM 5" line becomes "HIGH", turning ON Q12. The AGC voltage is cut off when Q12 is turned ON.

When the scan is in operation, the AGCR signal from the LOGIC UNIT turns OFF Q23. C132 is bypassed to reduce the AGC time constant.

### • WFM DEMODULATOR CIRCUIT



### 4-2-8 SQUELCH CIRCUIT (MAIN UNIT)

The IC-R100 has 2 squelch systems, S-meter squelch and noise squelch.

The noise squelch functions in FM mode. Some of the noise components in the AF signal from IC1 are applied to IC1 (pin 10) via a de-emphasis circuit (R17, C28, C29). This de-emphasis circuit is an integrated circuit with frequency characteristics of -6 dB/octave.

The active filter section in IC1 amplifies noise components of frequencies of 20 kHz and above, and outputs the resulting signals from pin 11. Output signals are rectified by D2 and D3, and converted to DC voltage.

The rectified voltage triggers the squelch switch (Q3) and then is applied to a squelch trigger circuit (IC1, pin 12). The output level from IC1 (pin 14) becomes "LOW" and turns ON D29. The AF signal is muted when the output level from IC6(b) (pin 7) becomes "LOW."

The S-meter squelch functions in either AM or WFM mode. The S-meter squelch signal from IC1 (pin 11) is applied to IC6(a) through the squelch switch (Q3) to compare with a reference voltage controlled by R86 on the LOGIC UNIT. When this reference voltage level is higher than the S-meter squelch level from IC1 (pin 11), D28 is turned ON. The output level from IC6(b) (pin 7) becomes "LOW" to mute an AF signal line.

When the S-meter squelch is in operation, Q19 is turned ON to cut off the noise squelch.

### 4-2-9 AFC CIRCUIT (MAIN UNIT)

This circuit automatically controls the receive frequency to compensate for the frequency drift in FM or AM mode.

IC2 is a monolithic IC which lights up "AFC" on the function display when AFC function is in operation. A current regulator (IC8) supplies a 10 V reference voltage to IC2 (pin 1) for comparison with the DC component in the detected FM or AM signal.

The frequency drift selects an output signal to control the receive frequency. The signal is output from IC2 (pin  $6\sim8$ ) and applied to the LOGIC UNIT.

### 4-2-10 AF AMP CIRCUIT (MAIN UNIT)

The de-modulated signals are applied to an AF mute circuit consisting of IC5(b)  $\sim$  IC5(d) and then amplified at Q15. The amplified signals are applied to the [VOL] control (R1) on the VR UNIT. When the squelch is closed, IC5 cuts off the AF signals like an AF mute switch. The AF signals are power-amplified at an AF power amplifier (IC7) to drive a speaker.

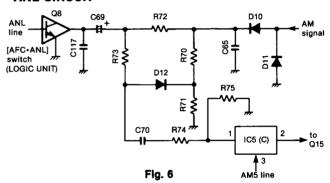
### 4-2-11 ANL CIRCUIT (MAIN UNIT)

This circuit eliminates the noise components to obtain clear reception in AM mode.

The ANL circuit consists of R70~R73, D12, C69, and Q8. The detector output from D10 and D11 is applied to the anode of D12 through R72 and R73. The detector output is also applied to the cathode of D12, passing through R70 where it is divided by R70 and R71.

When the [AFC • ANL] switch is turned OFF, the anode voltage of D12 is higher than the cathode voltage. D12 is therefore activated. However, when the [AFC • ANL] switch is turned ON, the ANL signal line becomes "HIGH" to turn ON Q8. C69 and C117 are grounded. Therefore the detector output, including pulses, is only applied to the cathode of D12. The cathode voltage becomes higher than the anode voltage and D12 shuts OFF just at the moment when the pulses are received. The AF signal (excluding pulses) then passes through D12 and is applied to IC5(c).

### ANL CIRCUIT



### 4-3 PLL CIRCUITS

### 4-3-1 GENERAL (PLL UNIT)

The PLL circuit, using a one chip modulus prescaler (IC3), directly generates the 1st LO frequencies with 4 VCO's on the TUNER UNIT. The modulus prescaler (IC3) sets the dividing ratio based on serial data from the CPU, and compares the phases of VCO signals and the reference oscillator frequency. The PLL IC (IC3) detects the out-of-step phase and outputs it from IC3 (pin 5). A reference frequency is oscillated at X1.

# 4-3-2 REFERENCE OSCILLATOR CIRCUIT (PLL UNIT)

A 12.6 MHz reference frequency is produced by the local oscillator section of IC3 and X1. C14 provides frequency control.

### 4-3-3 LOOP FILTER CIRCUIT (PLL UNIT)

Phase-detected signals from IC3 (pin 5) are converted to DC voltage by a loop filter consisting of an active filter (Q2 and Q3).

The DC voltage (PLL lock voltage) is fed back to the TUNER UNIT (EP2) through an LV signal line to control the VCO oscillation frequency.

The unlock signal is output from IC3 (pin 7).

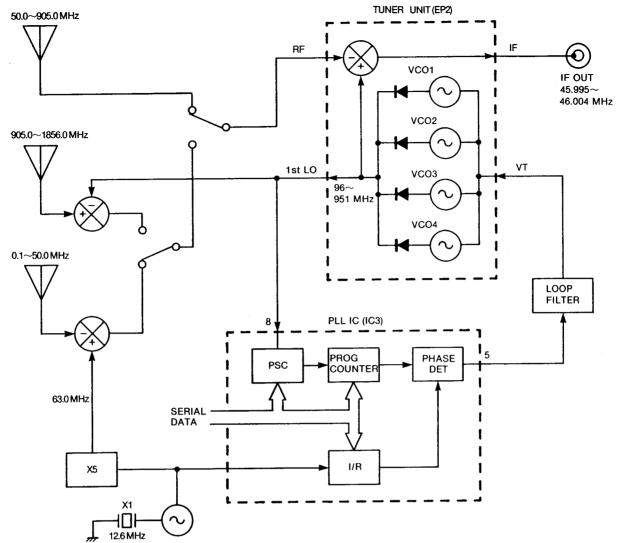


Fig. 7

### 4-3-4 VCO CIRCUIT (PLL UNIT)

Each of the 4 VCO's oscillates a different frequency on the TUNER UNIT (EP2). The Fig. 7, 8 shows the relations between VCO and oscillation frequency.

vco	OSCILLATION FREQUENCY
VCO1	96.000~141.750 MHz
VCO2	141.750~267.750 MHz
VCO3	267.750~521.750 MHz
VCO4	521.750~951.000 MHz

Fig. 8

The signals are buffer-amplified at IC4 and then applied to IC3 (pin 8). The buffer amplifier (IC4) protects the PLL output signal against VCO oscillation.

# 4-3-5 DC-DC CONVERTER CIRCUIT (PLL UNIT)

IC5 is a DC-DC converter which creates approximately 30 V DC from 10 V DC to obtain wide range lock voltages for the PLL circuit.

### 4-4 POWER SUPPLY CIRCUITS

### 4-4-1 VOLTAGE LINES

LINE	DESCRIPTION			
13.8 V	13.8 V DC controlled by the PWS signal line.			
5 V	Common 5 V converted from the 13.8 V line at IC 9 on the MAIN UNIT.			
10 V	10 V DC converted from the 13.8 V line. IC8 on the MAIN UNIT is a switching regulator IC and converts IC5 output into approx. 30 V DC.			

### 4-4-1 SWITCHING CIRCUIT (MAIN UNIT)

This circuit consists of Q17, Q18 and Q30. The circuit corresponds to the high-rippled DC voltage which an AC adapter contains. When a ripple is present in DC voltage, a ripple filter (C129, R132) eliminates the ripple to obtain clear reception.



# 4-4-2 5 V AND 10 V REGULATOR CIRCUITS (MAIN UNIT)

The DC voltages are supplied from regulator circuits corresponding to the voltages. They are regulated at the following circuits using 13.8V DC.

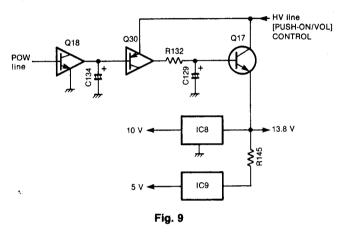
### (1) 5 V REGULATOR (MAIN UNIT)

5V DC is regulated by the three-terminal voltage regulator (IC9) and applied to the MAIN and PLL UNITS.

### (2) 10 V REGULATOR (MAIN UNIT)

10V DC is regulated by the three-terminal voltage regulator (IC8) and applied to the MAIN and PLL UNITS.

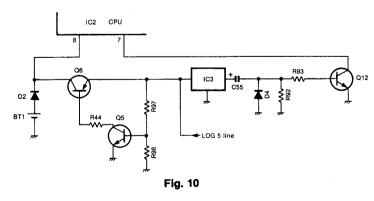
### • 5 V AND 10 V REGULATOR CIRCUITS



# 4-4-3 CPU POWER SUPPLY CIRCUIT (LOGIC UNIT)

The DC voltage is applied to the main CPU (IC2, pin 8) via D2 from the lithium backup battery (BT1) to provide backup for the memory contents regardless of the power switch condition.

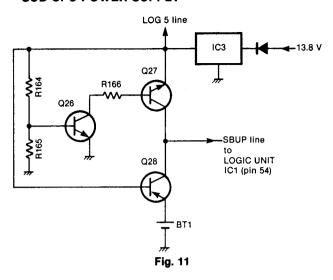
### • CPU POWER SUPPLY AND CPU RESET CIRCUITS



# 4-4-4 SUB CPU POWER SUPPLY CIRCUIT (MAIN AND LOGIC UNITS)

The DC voltage is applied to the sub CPU (IC1, pin 54) from the lithium backup battery (BT1) to provide backup for the memory contents. This circuit is controlled by Q28.

### SUB CPU POWER SUPPLY



### 4-5 OTHER CIRCUITS

### 4-5-1 DIMMER CIRCUIT (LOGIC UNIT)

The dimmer circuit consists of Q8, Q9 and other components and drives backlights (DS2), ensuring that brightness does not change even with a change of power supply.

When the main CPU (IC2, pin 28) changes its output level, Q8 and Q9 change the base voltage and collector current.

When the main CPU (IC2, pin 28) outputs "LOW", the base of Q9 obtains 5V through R89 to light up DS2.

When the main CPU (IC2, pin 28) outputs "HIGH" to turn ON, Q1, R89 and R90 divide 5 V into three voltages. The three voltage portions are applied to the base of Q9. Therefore, the collector voltage from Q8 decreases to dim the brightness of the lamp (DS2).

### 4-5-2 CPU RESET CIRCUIT (LOGIC UNIT)

When the power switch is turned OFF, the reset circuit functions as a three-terminal voltage regulator IC (IC3) which resets the main CPU (IC2). IC3 detects  $\pm 5$  V when the DC voltage is applied to the input terminal of IC3 and outputs 5 V. The voltage of the leading edge is applied to a time constant (C55, R93) to obtain sufficient reset time and inverted to supply a reset signal to the main CPU (IC2, pin 7) at Q12.

The differential circuit (C54, R84) functions while an AND circuit (D3, D5) pushes and holds the [CLK], [FUNC], and [ENT] switches. When the power switch is turned ON, the differential circuit outputs a pulse to reset CPU.

### 4-5-3 REAL TIME CLOCK (LOGIC UNIT)

This receiver has a clock IC (IC1) with timer function. A 32.768 kHz is oscillated at X2 for clock reference. When the power switch is turned OFF, the DC voltage is applied to the sub CPU (IC1) from the lithium battery to provide backup for clock operation.

### 4-6 LOGIC CIRCUITS (LOGIC UNIT)

The LOGIC UNIT has two CPUs installed as main and sub CPUs for a variety of operating functions.

### 4-6-1 MAIN CPU (IC2) PORT ALLOCATIONS

### (1) INPUT PORT

PORT NUMBER	PORT NAME	PIN NUMBER	DESCRIPTION
P10	К0	56	When the port becomes "LOW," the CPU detects that the [0] key has been pushed.
P11	K1	57	When the port becomes "LOW," the CPU detects that the [1] key has been pushed.
P12	K2	58	When the port becomes "LOW," the CPU detects that the [2] key has been pushed.
P13	K3	59	When the port becomes "LOW," the CPU detects that the [3] key has been pushed.
P14	K4	61	When the port becomes "LOW," the CPU detects that the [4] key has been pushed.
P15	K5	62	When the port becomes "LOW," the CPU detects that the [5] key has been pushed.
P16	K6	63	When the port becomes "LOW," the CPU detects that the [6] key has been pushed.
P17	K7	64	When the port becomes "LOW," the CPU detects that the [7] key has been pushed.
P20	_	_	Not used.
P21	STOP	76	When the port becomes "LOW," the CPU switches to the backup mode.
P22	DCK	77	Input port for the main dial clock pulses.
P23	ONEUP	79	Input port for control signals to communicate with the sub CPU. "HIGH" voltage is applied to the terminal every second.
P24	DDN	80	Input port for the DOWN signal of the main dial.
P25	DUP	81	Input port for the UP signal of the main dial.
P26			Not used.
P27	SIN	83	Input port for serial data.
P40	K8	49	When the port becomes "LOW," the CPU detects that the [8] key has been pushed.

PORT	PORT	PIN	DESCRIPTION
NUMBER	NAME	NUMBER	DESCRIPTION
P41	K9	48	When the port becomes "LOW," the CPU detects that the [9] key has been pushed.
P42	KDP	47	When the port becomes "LOW," the CPU detects that the [•] key has been pushed.
P43	KENT	46	When the port becomes "LOW," the CPU detects that the [ENT] key has been pushed.
P44	KUP	45	When the port becomes "LOW," the CPU detects that the [UP] key has been pushed.
P45	KDN	44	When the port becomes "LOW," the CPU detects that the [DOWN] key has been pushed.
P46	_	43	Not used.
P47		42	Not used.
P65	BUSY	25	When the port becomes "HIGH," the CPU detects that the receiver receives signals.
P66	PWS	24	When the port becomes "LOW," the CPU detects that the power switch has been turned ON.
P67	CLKS	23	When the port becomes "LOW," the CPU detects that the clock switch has been turned ON.
P70~ P72	VER1~ VER3	67~69	Used for selecting a version when only the CPU is reset.
P73	AUTO	71	When the port becomes "LOW," the 9 kHz step of the TS function is selected. This TS selection is only possibe after the CPU has been reset.
P74	FUP	72	AFC control signal input. When the port becomes "LOW," AFC controls the receive frequency for the higher frequency direction.
P75	FDN	73	AFC control signal input. When the port becomes "LOW," AFC controls the receive frequency for the lower fequency direction.
P76	FCNT	74	AFC control signal input. When the port becomes "LOW," the CPU detects that the displayed frequency (center frequency) has been received.
РТ0	SM	93	A/D signal input. Used for indicating signal strength on the S-indicator.
PT1~ PT7	_	94, 1~6	Not used.

### (2) OUTPUT PORT

PORT NUMBER	PORT NAME	PIN NUMBER	DESCRIPTION
P00~ P04	DA0~ DA4	14~18	Output D/A converted signals which control the frequency for lower 10 kHz unit.
P05	FM	19	The port becomes "HIGH" when FM mode is selected.
P06	WFM	20	The port becomes "HIGH" when WFM mode is selected.
P07	АМ	21	The port becomes "HIGH" when AM mode is selected.
P30	ENA	85	Outputs a strobe signal for the PLL IC chip.
P31	SSTB	86	Outputs a strobe signal for the sub CPU.
P32	СК	87	Outputs serial clock signals.
P33	DATA	88	Outputs serial data.
P34	_	89	Not used.
P35	BEEP	90	Outputs 1 kHz or 500 Hz square waves used as a beep tone.
P36	SRST	91	Outputs a pulse of 15µsec. width when the CPU is reset.
P37	_	92	
P50	BS0	40	Not used.
P51	BS1	39	
P52	BS2	38	Output band control signals. See the table shown in the section.
P53	HF	37	
P54	1G	36	PLL UNIT.
P55	1GF	34	
P56	PRE	33	The port becomes "HIGH" when the [PRE/ATT] switch is pushed once.
P57	ATT	32	The port becomes "HIGH" when the [PRE/ATT] switch is pushed twice.
P60	POW	30	The port becomes "HIGH" when the [PUSH-ON/VOL] switch is ON.
P61	ANL	29	The port becomes "HIGH" when the [AFC • ANL] switch is ON.
P62	DIM	28	The port becomes "HIGH" when the [DIM] switch is ON.
P63	AGCR	27	The port becomes "LOW" when the AGC is set to FAST in scanning operation.
P64		26	Not used.

### 4-6-2 SUB CPU PORT ALLOCATIONS

PORT NUMBER	PORT NAME	PIN NUMBER	DESCRIPTION
P00	STOP	38	When the port becomes "LOW," the CPU enters the backup mode.
P01	СК	39	Input port for serial clock signals.
P02	S DATA	40	Outputs serial data.
P03	DATA	41	Input port for serial data.
P10	SSTB	42	Input port for a strobe signal.
P60	ONE UP	60	This port becomes "HIGH" every one second.

### SECTION 5 MECHANICAL PARTS AND DISASSEMBLY

### **5-1 FRONT PARTS**

LABEL Number	ORDER NO.	DESCRIPTION	ату.
①	8930013320	545 Rubber	1
2	8810006130	BiH M2.6 × 5 ZK	5
3	8930018550	Sponge (CG)	1
4	8110004010	Top cover	1
(5)	8210005530	Front panel (incl. window)	1
6	8830000550	VR nut (E)	1
7	8610006480	Knob N152 [PUSH-ON/VOL] [SQUELCH]	2
8	8610006470	Knob N151 [TUNING CONTROL]	1
9	8210005540	10 Key rubber	1
10	8930018320	Blind sheet	1
11)	8810001720	PH B0 No.0-3 M1.4 × 4	5
12	7210001840	Variable resistor RV – 168 [PUSH-ON/VOL]	1
(13)	8810003960	Setscrew (A) M2.6 × 5	5
(14)	2250000050	Encoder EVQ-WQGF15 24B [TUNING CONTROL]	1
(15)	8010009910	Sub chassis	1
16	8930018050	LCD cover	1
17	8930017850	LCD holder	1
(18)	5030000530	LCD HLC9792-01-2300	1
19	8930018360	LCD filter	1
20	8010009710	851 Reflector	1

Screw abbreviations

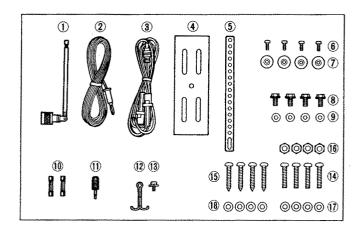
BiH: Binding head

ZK: Black

PH: Pan head

B0: Self-tapping

### **5-2 ACCESSORIES**



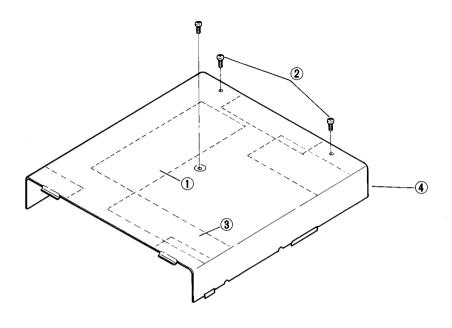
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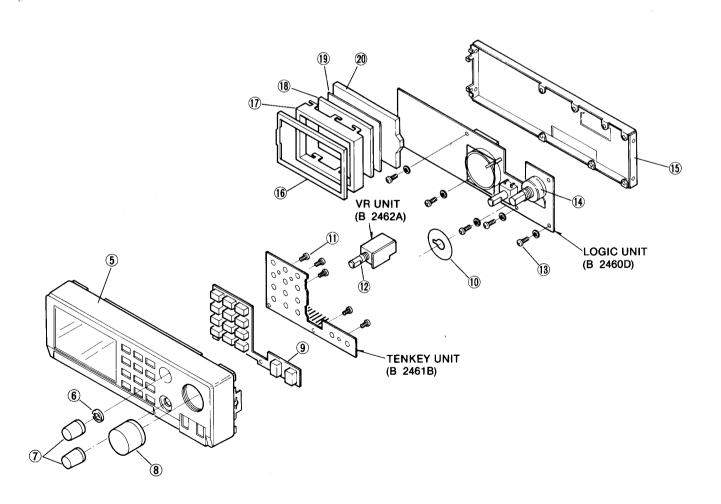
LABEL NUMBER	ORDER NO.	DESCRIPTION	QTY.
①	3310000540	VHF/UHF telescoping antenna FA-5N	1
2	8900000460	HF wire antenna OPC-069	1
3	Optional product	DC power cable OPC-131	1
4	8010004060	Mounting bracket	1
(5)	8010008710	150 Mounting support bracket	1
6	8810000150	PH M2.6 × 6	4
1	8930002820	Rubber feet (D)	4
8	8820000530	Mounting bolt	4
9	8850000140	Flat washer M4 NI BS	4
10	5210000040	Fuse FGB 2A	2
11)	5610000020	AP313 3.5φ CS plug	1
(12)	8930018190	851 cable tie	1
(13)	8810003360	Setscrew M3 × 6	1
14)	8810003870	PH M5 × 20	4
(15)	8810005840	PH (A) B0 M5 × 20	4
16	8830000120	Nut M5	
17	8850000150	Flat washer M5 NI BS	
18	8850000440	Spring washer M5 NI	4

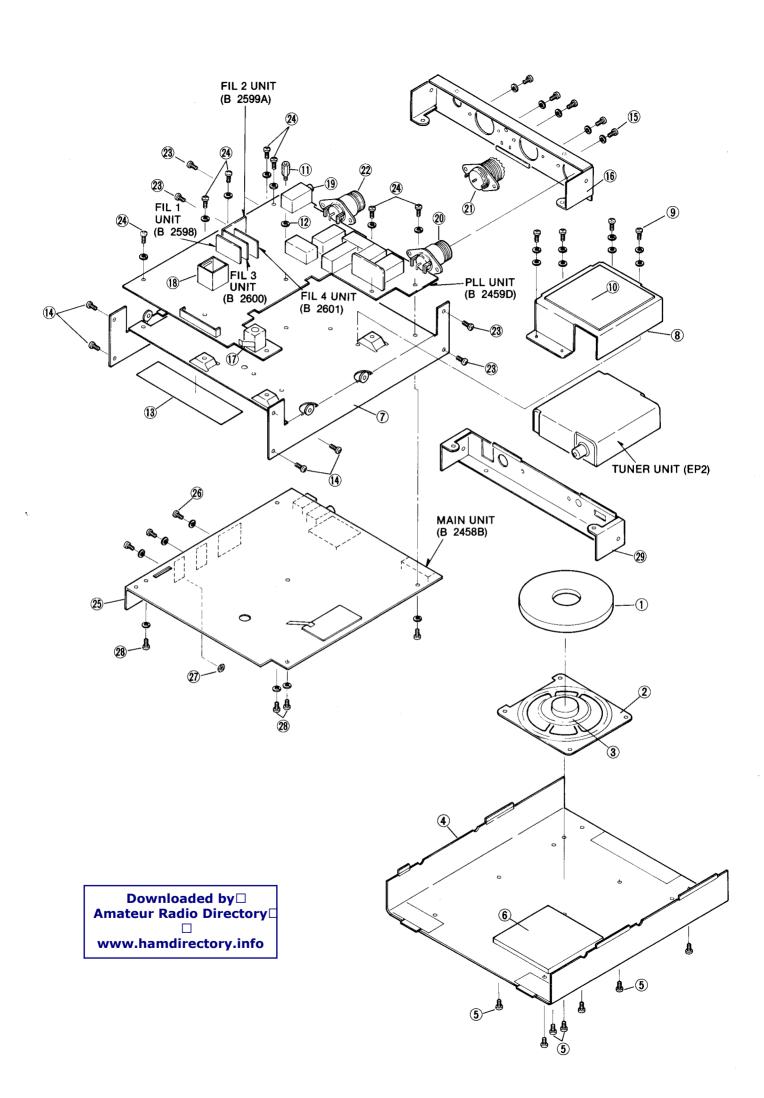
Screw abbreviations

PH: Pan head BS: Brass

NI: Nickel B0: Self-tapping







### **5-3 CHASSIS PARTS**

LABEL Number	ORDER NO.	DESCRIPTION	QTY.
1	8930005360	Sponge	1
2	8930017810	833 SP plate	1
3	2510000470	Speaker EAS-6P100SA	1
4	8110004020	Bottom cover	1
5	8810006130	BiH M2.6 × 5 ZK	4
6	8930001540	Sponge (Z)	1
7	8010009920	Chassis	1
8	8930018370	Tuner base cover	1
9	8810003350	Setscrew (C) M3 × 5	4
10	8930018570	Rubber sheet	1
11)	8930018580	Standoff (BB)	1
12	8850000420	Spring washer M3 NI	1
13	8930007430	Shield plate	1
14)	8810002110	FH M2.6 × 5	4
(15)	8810003150	Setscrew (A) M3 × 5	6
16	8010009870	Back panel (top)	1
17	8930001160	Ground spring	1
18	8510000020	194 shield case	1
(19)	6450000970	ANT connector HSJ0914-01-140 [ANT SEL]	1
20	6510000360	ANT connector NR-DS-E 02 [50MHz~905MHz]	1
21)	6510000410	ANT connector MR-DS-E 02 [0.5MHz~50MHz]	1
22	6510000360	ANT connector NR-DS-E 02 [905MHz~1800MHz]	1
23	8810002160	FH M3 × 5	4
24)	8810003150	Setscrew (A) M3 × 5	7
25	8410001500	MAIN heatsink	1
26	8810000240	PH M3 × 8	3
27	8830000100	Nuts M3 3	
28	8810003150	Setscrew (A) M3 × 5	
29	8010009880	Back panel (bottom)	1

Screw abbreviations BiH: Binding head ZK: Black PH: Pan head NI: Nickel FH: Flat head

# SECTION 6 PARTS LIST

### [VR UNIT]

REF. NO.	ORDER NO.	DESCRIPTION	
R1	7210001840	Variable Resistor	RV-168 (RK0971112) [PUSH-ON/OFF]
EP1	0910025801	P.C. Board	B 2462A (VR)

### [TENKEY UNIT]

REF. NO.	ORDER NO.	DESCRIPTION	
EP1	0910025912	P.C. Board	B 2461B (TENKEY)

### [LOGIC UNIT]

REF. NO.	ORDER NO.	DESCRIPTION	
IC1	1140001260	IC	μPD75304GF-084-3B 9
IC2	1140001570	IC	μPD78224GJ-533-5B G
IC3	1110001550	IC	S-8054ALB-LM-T1
Ì			
Q1	1590000420	Transistor	RN1404 (TE85R)
Q2	1590000420	Transistor	RN1404 (TE85R)
Q3	1590000450	Transistor	FMG4 T148
Q5	1530000160	Transistor	2SC2712-Y (TE85R)
Q6	1510000110	Transistor	2SA1162-Y (TE85R)
Q7	1590000420	Transistor	RN1404 (TE85R)
Q8	1510000110	Transistor	2SA1162-Y (TE85R)
Q9	1530000160	Transistor	2SC2712-Y (TE85R)
Q12	1530000160	Transistor	2SC2712-Y (TE85R)
D2	1750000030	Diode	1SS187 (TE85R)
D3	1750000020	Diode	1SS184 (TE85R)
D4 .	1750000040	Diode	1SS190 (TE85R)
D5	1750000020	Diode	1SS184 (TE85R)
X1	6050005090	Crystal	CR-245
X2	6050005800	Crystal	DT-26S 32.768KHZ
Х3	6060000190	Crystal	CSA9.21MT2
R1	7030000300	Resistor	MCR10EZHJ 220 Ω (221)
R2	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R3	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R4	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R5	7030000620	Resistor	MCR10EZHJ 100 kΩ (104)
R7	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R8	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R9	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)

### [LOGIC UNIT]

	T	1	
REF. NO.	ORDER NO.		DESCRIPTION
R10	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R11	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R12	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R13	7030000970	Resistor	MCR10EZHJ 2.2 MΩ (225)
R14	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R15	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R16	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R17	7030000500	Resistor	MCR10EZHJ 10 kΩ (103)
R18	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R19	7030000620	Resistor	MCR10EZHJ 100 kΩ (104) MCR10EZHJ 47 kΩ (473)
R20 R21	7030000580	Resistor Resistor	MCR10EZHJ 47 kΩ (473)
R22	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R23	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R24	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R25	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R26	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R27	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R28	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R29	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R30	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R31	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R32	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R33	7030000580	Resistor	MCR10EZHJ 47 kΩ (473) MCR10EZHJ 47 kΩ (473)
R34 R35	7030000580	Resistor Resistor	MCR10EZHJ 47 kΩ (473)
R36	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R37	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R38	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R39	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R41	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R42	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R43	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R44	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R45	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R46	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R47	7030000380	Resistor	MCR10EZHJ 1 kΩ (102) MCR10EZHJ 1 kΩ (102)
R48 R49	7030000380 7030000380	Resistor Resistor	MCR10EZHJ 1 kΩ (102)
R50	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R51	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R52	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R53	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R54	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R55	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R56	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R57	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R58	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R59	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R60	7030000380 7030000380	Resistor Resistor	MCR10EZHJ 1 kΩ (102) MCR10EZHJ 1 kΩ (102)
R61 R62	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R63	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R64	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R65	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R66	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R67	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R68	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R69	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R70	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R71	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R72	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R73	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)

### [LOGIC UNIT]

	ONT		
REF. NO.	ORDER NO.	D	ESCRIPTION
R74	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R75	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R76	7030000380 7030000380	Resistor Resistor	MCR10EZHJ 1 kΩ (102) MCR10EZHJ 1 kΩ (102)
R77	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R79	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R80	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R81	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R82	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
R83	7410000520 7030000580	Resistor Array Resistor	RKM7L 104J MCR10EZHJ 47 kΩ (473)
R84 R86	7210001830	Variable Resistor	RV-167 (RK09K)
R87	7030000410	Resistor	MCR10EZHJ 1.8 kΩ (182)
R88	7030000390	Resistor	MCR10EZHJ 1.2 kΩ (122)
R89	7030000550	Resistor	MCR10EZHJ 27 kΩ (273)
R90	7030000590	Resistor Resistor	MCR10EZHJ 56 kΩ (563) MCR10EZHJ 220 kΩ (224)
R92 R93	7030000660	Resistor	MCR10EZHJ 100 kΩ (104)
R94	7030000580	Resistor	MCR10EZHJ 47 kΩ (473)
R95	7030000660	Resistor	MCR10EZHJ 220 kΩ (224)
R96	7030000660	Resistor	MCR10EZHJ 220 kΩ (224)
R97	7030000620	Resistor	MCR10EZHJ 100 kΩ (104) MCR10EZHJ 27 kΩ (273)
R98 R99	7030000550 7030000500	Resistor Resistor	MCR10EZHJ 27 kΩ (273) MCR10EZHJ 10 kΩ (103)
1100	700000000	1103/310/	MOTTOLLING TO KEE (100)
C2	4030004520	Ceramic	C2012 SL 1H 220J- T-A
СЗ	4030004520	Ceramic	C2012 SL 1H 220J- T-A
,C5	4030000920	Ceramic	GRM40 CH 150J 50P T
C6 C7	4030000920 4030004760	Ceramic Ceramic	GRM40 CH 150J 50P T C2012 JF 1E 104Z- T-A
C9	4030004760	Ceramic	C2012 JF 1E 104Z- T-A
C10	4030004610	Ceramic	C2012 SL 1H 101J- T-A
C11	4030004610	Ceramic	C2012 SL 1H 101J- T-A
C17	4030004740	Ceramic	C2012 JB 1H 472K- T-A C2012 JB 1H 472K- T-A
C18 C19	4030004740 4030004740	Ceramic Ceramic	C2012 JB 1H 472K- T-A
C20	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C21	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C22	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C23	4030004740 4030004740	Ceramic Ceramic	C2012 JB 1H 472K- T-A C2012 JB 1H 472K- T-A
C24 C25	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C26	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C27	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C28	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C29	4030004740 4030004740	Ceramic Ceramic	C2012 JB 1H 472K- T-A C2012 JB 1H 472K- T-A
C30 C31	4030004740	Ceramic Ceramic	C2012 JB 1H 472K- 1-A
C32	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C33	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C34	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C35	4030004740	Ceramic	C2012 JB 1H 472K- T-A C2012 JB 1H 472K- T-A
C36 C37	4030004740 4030004740	Ceramic Ceramic	C2012 JB 1H 472K- 1-A
C38	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C39	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C40	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C41	4030004740	Ceramic	C2012 JB 1H 472K- T-A C2012 JB 1H 472K- T-A
C42 C43	4030004740 4030004740	Ceramic Ceramic	C2012 JB 1H 472K- 1-A
C43	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C45	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C46	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C47	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C48 C49	4030004740 4030004740	Ceramic Ceramic	C2012 JB 1H 472K- T-A C2012 JB 1H 472K- T-A
U49	4000004740	Jeraille	OLUIZ UD III TIEN I'A

### [LOGIC UNIT]

REF. NO.	ORDER NO.	D	ESCRIPTION
C50	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C51	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C52	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C53	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C54	4030004720	Ceramic	C2012 JB 1H 102K- T-A
C55	4510001150	Electrolytic	50 MS7 R47 μF
C56	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C57	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C58	4030004740	Ceramic	C2012 JB 1H 472K- T-A
DS1 DS2	5030000530 5080000150	LCD Lamp	HLC9792-01-2300 HRS-7219A
S1	2250000050	Encoder	EVQ-WQGF15 24B [TUNING CONTROL]
BT1	3020000130	Lithium Battery	CR3032-1T2
EP1	0910025784	P.C. Board	B 2460D (LOGIC)
EP2	8930017610	LCD contact strip	SRCN-851

### [MAIN UNIT]

REF. NO.	ORDER NO.	C	DESCRIPTION
IC1	1110000630	ıc	MC3357P
IC2	1110001160	IC	BA695
IC3	1110002010	IC	MC3356P
IC4	1120001690	IC	M5223L
IC5	1130001000	IC	μPD4066BC
IC6	1120001690	IC .	M5223L
IC7	1110001360	IC	μPC1242H
IC8	1180000590	IC	TA78DL10S
IC9	1110002020	IC	TA7805S
IC10	1120001690	IC	M5223L
IC11	1180000010	IC IC	TA78L005AP
Q1	1530002210	Transistor	2SC3776-D
Q2	1580000110	FET	3SK74 M
Q3	1530000591	Transistor	2SC2785 EL
Q4	1530000150	Transistor	2SC2668-O
Q5	1530000591	Transistor	2SC2785 EL
Q6	1530000591	Transistor	2SC2785 EL
Q7	1530000150	Transistor	2SC2668-O
Q8	1590000350	Transistor	RN1204
Q9	1590000350	Transistor	RN1204
Q10	1590000350	Transistor	RN1204
Q11	1530002710	Transistor	2SC2785 KL
Q12	1590000350	Transistor	RN1204
Q13	1590000370	Transistor	RN2204
Q15	1530000110	Transistor	2SC2458-GR
Q16	1530000591	Transistor	2SC2785 EL
Q17	1540000200	Transistor	2SD1406 Y
Q18	1590000350	Transistor	RN1204
Q19	1590000350	Transistor	RN1204

### [MAIN UNIT]

### [MAIN UNIT]

	REF. NO.	ORDER NO.	C	DESCRIPTION
Ì	Q20	1530000110	Transistor	2SC2458-GR
	Q21	1530000110	Transistor	2SC2458-GR
ı	Q22	1530000110	Transistor	2SC2458-GR
ı	Q23	1590000350	Transistor	RN1204
ı	Q24	1530000110	Transistor	2SC2458-GR
I	Q25	1590000310	FET	2SJ105-GR
I	Q26	1530000100	Transistor	2SC2458-Y
ı	Q27	1510000070	Transistor	2SA1048-Y
I	Q28	1510000070	Transistor	2SA1048-Y
ı	Q29	1590000350	Transistor	RN1204
ı	Q30	1590000370	Transistor	RN2204
ı	Q31	1590000350	Transistor	RN1204
ı	Q32	1530000110	Transistor	2SC2458-GR
	D1	1710000050	Diode	1SS53
I	D2	1790000070	Diode	1SS237
I	D3	1790000070	Diode	1SS237
	D4	1710000050	Diode	1\$\$53
	D5	1710000050	Diode	1SS53
j	D6	1710000050	Diode	1SS53
Į	D7	1710000050	Diode	1\$\$53
	D8	1720000290	Varicap	1T32
	D9	1730000120	Zener	RD6.2E B2
	D10	1710000330	Diode	1K60
ı	D11	1710000330	Diode	1K60
ı	D12	1710000600	Diode	1SS254
1	D13	1710000160	Diode	188133
Ì	D14	1710000160	Diode	188133
ı	D15	1710000160	Diode	1SS133
ı	D17	1790000070	Diode	1SS237
ı	D18	1790000070	Diode	1SS237
ı	D19	1710000160	Diode	1SS133
ı	D20	1710000160	Diode	1SS133
ı	D21	1710000160	Diode	188133
ı	D22	1710000160	Diode	1SS133
ı	D25	1710000050	Diode	1SS53
ı	D26	1710000050	Diode	1SS53
ı	D27	1790000070	Diode	1SS237
ı	D28	1710000160	Diode	1SS133
ı	D29	1710000160	Diode	1SS133
ı	D30	1710000350	Diode	1N4002
ı	D31	1710000160	Diode	1SS133
I	D31	1710000100	Diode	U05G
Į	D32	1710000140	Diode	1SS133
Į	D33	1710000160	Diode	1SS133
	D34	1710000160	Diode	1SS133
j	D36	1710000100	Diode	1SS53
	D36 D37	1710000050	Diode	1SS53
	50.	., 1000000	2.000	.5300
	X1	6050002440	Crystal	CR-114
l	X2	6070000010	Discriminator	CDB455C7A
l	Х3	6050006680	Crystal	CR-318
l	X4	6070000070	Discriminator	CDA10.7MC4A-A
ĺ	FI1	2010001070	Filter	46M20AU
l	FI2	2010001160	Filter	10M15B7
	FI3	2030000030	Ceramic Filter	KBF-455R-15A
ļ	FI4	2030000040	Ceramic Filter	KBF-455R-6AS
	FI5	2020000670	Ceramic Filter	SFE10.7MS2-A
-1		1		
ļ	11	615000000	Coil	LS-114
	L1	6150000990	Coil	LS-114 LS-114
	L1 L2 L3	6150000990 6150000990 6150001480	Coil Coil Coil	LS-114 LS-114 LS-164

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REF. NO.	ORDER NO.	D	ESCRIPTION
L4	6150001480	Coil	LS-164
L5	6180000790	Coil	LAL 03NA 1R5M
L6	6180000880	Coil	LAL 03NA 100K
L7	6150002550	Coil	LS-284
L8	6150002550	Coil	LS-284
L9	6180000880	Coil	LAL 03NA 100K
L10	6150002290	Coil	LS-240
L11	6180002270	Coil	LAL 03NA 470K
L12	6170000140	Coil	LW-15
R1	7010003280	Resistor	ELR20J 100 Ω
R2	7010004230	Resistor	R20J 2.2 kΩ
R3	7010004230	Resistor	R20J 2.2 kΩ
R4	7510000260	Thermistor	ERT-D2ZGL102S R20J 4.7 kΩ
R5	7010004270 7010003280	Resistor Resistor	ELR20J 100 Ω
R6	7010003280	Resistor	ELR20J 100 Ω
R7 R8	7010003280	Resistor	ELR20J 10 kΩ
R9	7010003530	Resistor	R20J 1 kΩ
R10	7010004130	Resistor	ELR20J 47 Ω
R11	7010004070	Resistor	R20J 100 Ω
R12	7010003620	Resistor	ELR20J 47 kΩ
R13	7010003420	Resistor	ELR20J 1.5 kΩ
R14	7010003420	Resistor	ELR20J 1.5 kΩ
R15	7010003620	Resistor	ELR20J 47 kΩ
R16	7010003420	Resistor	ELR20J 1.5 kΩ
R17	7010004150	Resistor	R20J 470 Ω
R19	7010004190	Resistor	R20J 1 kΩ
R20	7010003720	Resistor	ELR20J 330 kΩ
R21	7010004280	Resistor	R20J 5.6 kΩ
R22	7010003580	Resistor	ELR20J 22 kΩ
R23	7010004410	Resistor	R20J 47 kΩ ELR20J 4.7 kΩ
R24 R25	7010003480 7010003440	Resistor Resistor	ELR20J 2.2 kΩ
R26	7010003440	Resistor	R20J 220 Ω
R27	7010003580	Resistor	ELR20J 22 kΩ
R28	7010003520	Resistor	ELR20J 8.2 kΩ
R29	7010003280	Resistor	ELR20J 100 Ω
R30	7010003240	Resistor	ELR20J 47 Ω
R31	7010003450	Resistor	ELR20J 2.7 kΩ
R32	7010003440	Resistor	ELR20J 2.2 kΩ
R33	7010003440	Resistor	ELR20J 2.2 kΩ
R34	7010004230	Resistor	R20J 2.2 kΩ
R35	7010003480	Resistor	ELR20J 4.7 kΩ
R36	7510000270	Thermistor	ERT-D2ZHL462S ELR20J 18 kΩ
R37	7010003560	Resistor	RH0651C14J2WA (103)
R38	7310000750 7010003620	Trimmer Resistor	ELR20J 47 kΩ
R39 R43	7010003620	Resistor	ELR20J 47 KΩ ELR20J 15 kΩ
R43	7010003550	Resistor	R20J 39 kΩ
R45	7010003360	Resistor	ELR20J 470 Ω
R46	7010004080	Resistor	R20J 120 Ω
R47	7010004070	Resistor	R20J 100 Ω
R48	7010000990	Resistor	R25XJ 47 Ω
R49	7010003280	Resistor	ELR20J 100 Ω
R50	7010003310	Resistor	ELR20J 180 Ω
R51	7010004320	Resistor	R20J 10 kΩ
R52	7010004270	Resistor	R20J 4.7 kΩ
R53	7010004450	Resistor	R20J 100 kΩ
R54	7010004410	Resistor	R20J 47 kΩ
R55	7310003210	Trimmer	EVN-2ACA00 B54 (503)
R56	7010004350	Resistor	R20J 18 kΩ R20J 22 kΩ
R57 R58	7010004370 7010003580	Resistor Resistor	ELR20J 22 kΩ
R59	7010003580	Resistor	R20J 3.3 kΩ
R60	7010004250	Resistor	R20J 120 kΩ

### [MAIN UNIT]

REF.	ORDER NO.		DESCRIPTION	REF. NO.	ORDER NO.		DESCRIPTION
R61	7010003600	Resistor	ELR20J 33 kΩ	R131	7010003080	Resistor	ELR20J 2.2 Ω
R62	7010003000	Resistor	R20J 12 kΩ	R132	7010003950	Resistor	R20J 10 Ω
R63	7010003510	Resistor	ELR20J 6.8 kΩ	R133	7010003400	Resistor	ELR20J 1 kΩ
R64	7010004450	Resistor	R20J 100 kΩ	R134	7010004650	Resistor	R50XJ 10 Ω
R65	7010004320	Resistor	R20J 10 kΩ	R135	7010003360	Resistor	ELR20J 470 Ω
R66	7010004110	Resistor	R20J 220 Ω	R136	7010004320	Resistor	R20J 10 kΩ
R67	7010003280	Resistor	ELR20J 100 Ω	R137	7010004340	Resistor	R20J 15 kΩ
R68	7010003560	Resistor	ELR20J 18 kΩ	R138	7010004450	Resistor	R20J 100 kΩ
R69	7010003580	Resistor	ELR20J 22 kΩ	R139	7010004450	Resistor	R20J 100 kΩ
R70	7010003620	Resistor	ELR20J 47 kΩ	R140	7010003700	Resistor	ELR20J 220 kΩ
R71	7010004320	Resistor	R20J 10 kΩ	R141	7010003690	Resistor	ELR20J 180 kΩ
R72	7010003720	Resistor	ELR20J 330 kΩ	R142	7310003220	Trimmer	EVN-2ACA00 B16 (105)
R73	7010003660	Resistor	ELR20J 100 kΩ	R143	7010003040	Resistor	ELR20J 1 Ω
R74	7010003710	Resistor	ELR20J 270 kΩ	R144	7010003780	Resistor	ELR20J 1 MΩ
R75	7010004370	Resistor	R20J 22 kΩ	R145	7070000610	Resistor	CRH100X R-02J 27 Ω (270) R20J 47 kΩ
R76	7010004410	Resistor	R20J 47 kΩ	R146	7010004410 7010003620	Resistor	ELR20J 47 kΩ
R77	7010004410	Resistor	R20J 47 kΩ	R147	7010003620	Resistor Resistor	ELR20J 3.3 kΩ
R78	7010004410	Resistor	R20J 47 kΩ	R148 R152	7010003460	Resistor	R20J 220 Ω
R79	7010003700	Resistor	ELR20J 220 kΩ ELR20J 3.3 kΩ	R152	73100004110	Trimmer	RH0651CN4J0TA (333)
R80 R82	7010003460 7010004450	Resistor Resistor	R20J 100 kΩ	R154	7010003770	Resistor	ELR20J 8.2 kΩ
R83	7010004450	Resistor	ELR20J 6.8 kΩ	R155	7010004450	Resistor	R20J 100 kΩ
R84	7010003310	Resistor	ELR20J 330 Ω	R156	7010004270	Resistor	R20J 4.7 kΩ
R85	7010003340	Resistor	ELR20J 330 Ω	R157	7010003630	Resistor	ELR20J 56 kΩ
R86	7010003530	Resistor	ELR20J 10 kΩ	R158	7510000330	Thermistor	ERT-D2ZIL154S
R87	7010004280	Resistor	R20J 5.6 kΩ	R159	7010004650	Resistor	R50XJ 10 Ω
R88	7010004350	Resistor	R20J 18 kΩ	R160	7070000270	Resistor	CRH100X
R89	7010004200	Resistor	R20J 1.2 kΩ				R-02J 100 Ω (101)
.R90	7010004350	Resistor	R20J 18 kΩ	R163	7010004030	Resistor	R20J 47 Ω
R91	7310003230	Trimmer	EVN-2ACA00 B15 (104)	R164	7010003610	Resistor	ELR20J 39 kΩ
R92	7010003550	Resistor	ELR20J 15 kΩ	R165	7010003530	Resistor	ELR20J 10 kΩ
R93	7010004030	Resistor	R20J 47 Ω	R166	7010003440	Resistor	ELR20J 2.2 kΩ
R94	7010003620	Resistor	ELR20J 47 kΩ	R167	7010004600	Resistor	R20J 2.2 MΩ
R95	7310003230	Trimmer	EVN-2ACA00 B15 (104)	R168	4610001360	Trimmer	EVML1GA00B15 100KB ELR20J 100 kΩ
R96	7010001490	Resistor	R25XJ 470 kΩ	R169	7010003660 7010004250	Resistor Resistor	R20J 3.3 kΩ
R97	7010004530	Resistor	R20J 470 kΩ R20J 1 MΩ	R170 R171	7010004230	Resistor	R20J 10 kΩ
R98	7010004570 7010004960	Resistor	ELR20J 1.5 MΩ	R172	7010004320	Resistor	R20J 220 kΩ
R99 R100	7010004980	Resistor Resistor	ELR20J 1.5 MΩ	R173	7310000680	Trimmer	RH0651C12J04A (101)
R100	7010003780	Resistor	ELR20J 1 MΩ	''''			, ,
R102	7010003780	Resistor	ELR20J 1 MΩ				
R105	7010003530	Resistor	ELR20J 10 kΩ	C1	4010000500	Ceramic	DD104 B 102K 50V
R106	7010004490	Resistor	R20J 220 kΩ	C2	4040000250	Barrier Layer	UAT 08X 473M
R107	7010003660	Resistor	ELR20J 100 kΩ	СЗ	4010000650	Ceramic	DD104 CH 050C 50V
R108	7010005220	Resistor	ELR20J 10 MΩ	C4	4010000330	Ceramic	DD105 SL 101J 50V
R109	7010003560	Resistor	ELR20J 18 kΩ	C5	4010000510	Ceramic	DD106 B 222K 50V
R110	7010004250	Resistor	R20J 3.3 kΩ	C6	4010000510	Ceramic	DD106 B 222K 50V
R111	7010004400	Resistor	R20J 39 kΩ	C7	4010000510	Ceramic	DD106 B 222K 50V
R112	7010003540	Resistor	ELR20J 12 kΩ	C8	4010000170	Ceramic	DD104 SL 200J 50V
R113	7010004340	Resistor	R20J 15 kΩ	C9	4010000170	Ceramic	DD104 SL 200J 50V
R114	7010003560	Resistor	ELR20J 18 kΩ	C10	4010000180	Ceramic Ceramic	DD104 SL 220J 50V DD104 SL 100D 50V
R115	7310003230	Trimmer	EVN-2ACA00 B15 (104)	C11 C12	4010000120 4010000520	Ceramic	DD104 3E 100D 30V
R116	7010003470	Resistor	ELR20J 3.9 kΩ	C12	4040000150	Barrier Layer	UAT 05X 472K
R117	7010003780 7010004450	Resistor Resistor	ELR20J 1 MΩ R20J 100 kΩ	C14	4010000340	Ceramic	DD105 SL 121J 50V
R118 R119	7010004450	Resistor	R20J 100 kΩ	C15	4010000500	Ceramic	DD104 B 102K 50V
R120	7010004450	Resistor	R20J 470 Ω	C16	4010000060	Ceramic	DD104 SL 040C 50V
R120	7010004150	Resistor	ELR20J 82 kΩ	C17	4010000330	Ceramic	DD105 SL 101J 50V
R121	7010003610	Resistor	ELR20J 39 kΩ	C18	4010000220	Ceramic	DD104 SL 330J 50V
R123	7010004250	Resistor	R20J 3.3 kΩ	C19	4010003460	Ceramic	DD104 UJ 330J 50V
R124	7010003440	Resistor	ELR20J 2.2 kΩ	C20	4010000800	Ceramic	DD105 CH 270J 50V
R125	7010003700	Resistor	ELR20J 220 kΩ	C21	4010000920	Ceramic	DD107 CH 820J 50V
R126	7010003620	Resistor	ELR20J 47 kΩ	C22	4010001020	Ceramic	DD111 CH 221J 50V
R127	7310003210	Trimmer	EVN-2ACA00 B54 (503)	C23	4510001970	Electrolytic	50 MS7 0R1 μF
R128	7010003620	Resistor	ELR20J 47 kΩ	C24	4040000260	Barrier Layer	UZE 08X 104M
R129	7010003100	Resistor	ELR20J 3.3 Ω	C25	4010000320	Ceramic	DD104 SL 820J 50V
R130	7010004190	Resistor	R20J 1 kΩ	C26	4010000520	Ceramic	DD108 B 472K 50V
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### [MAIN UNIT]

### ORDER RFF DESCRIPTION NO. NO. 25 SS 4R7 uF C27 4510002830 Electrolytic 4010000530 Ceramic DD112 B 103K 50V C28 C29 4010000460 Ceramic DD104 B 471K 50V C30 4040000090 **Barrier Layer UAT 04X 152K** DD104 SL 330J 50V 4010000220 C31 Ceramic C32 4040000190 **Barrier Layer UAT 05X 103K** C33 4510002940 Electrolytic 50 SS 1 μF **UAT 08X 473M** C34 4040000250 **Barrier Layer** DD104 B 102K 50V 4010000500 C35 Ceramic C36 4010000500 Ceramic DD104 B 102K 50V C37 4040000250 **Barrier Layer UAT 08X 473M** C38 4040000260 UZE 08X 104M **Barrier Layer** C39 4040000260 **Barrier Layer** UZE 08X 104M C40 4040000250 **Barrier Layer UAT 08X 473M** C41 DD104 SL 820J 50V 4010000320 Ceramic C42 4040000250 Barrier Layer **UAT 08X 473M** C43 4040000260 Barrier Layer UZE 08X 104M C44 4040000150 Barrier Laver UAT 05X 472K C45 4010000500 DD104 B 102K 50V Ceramic C46 4040000150 **Barrier Layer UAT 05X 472K** 16 SS 10 uF C47 4510002780 Electrolytic C48 4010003580 Ceramic DD106 UJ 101J 50V C49 4010003580 Ceramic DD106 UJ 101J 50V C50 4040000150 **Barrier Layer** UAT 05X 472K C51 4010000820 DD105 CH 330J 50V Ceramic C52 4010000500 Ceramic DD104 B 102K 50V DD104 SL 1B5C 50V C53 4010000030 Ceramic C54 4010000820 Ceramic DD105 CH 330J 50V C55 4010000520 Ceramic DD108 B 472K 50V DD108 B 472K 50V C56 4010000520 Ceramic **UAT 05X 103K** C57 4040000190 Barrier Layer DD104 SL 100D 50V C58 4010000120 Ceramic 50 MS7 0R1 μF C59 4510001970 Electrolytic C60 4010000500 Ceramic DD104 B 102K 50V C61 4040000260 Barrier Layer UZE 08X 104M Mylar F2D 50V 222K C62 4310000050 UZE 08X 104M C63 4040000260 **Barrier Layer** C64 4040000250 **Barrier Layer UAT 08X 473M** UAT 05X 472K C65 4040000150 **Barrier Layer** UP050 SL 220J C66 4020000620 Cylinder C67 4040000250 **Barrier Layer UAT 08X 473M** C68 4560000030 D55X5T 1H 473M Ceramic 4510001140 50 MS7 R22 μF C69 Electrolytic F2D 50V 222K C70 4310000050 Mylar C71 4040000260 Barrier Laver UZE 08X 104M 4010000260 DD104 SL 470J 50V C72 Ceramic **UAT 05X 103K** C73 4040000190 **Barrier Layer** C74 4040000190 **UAT 05X 103K** Barrier Laver C75 4040000190 **UAT 05X 103K Barrier Layer** 25 SS 4R7 μF C76 4510002830 Electrolytic C77 4010000520 Ceramic DD108 B 472K 50V C78 4040000260 **Barrier Layer UZE 08X 104M** F2D 50V 223K C79 4310000060 Mylar C80 4010000460 DD104 B 471K 50V Ceramic C81 4040000190 **UAT 05X 103K Barrier Laver** C82 4510002780 Electrolytic 16 SS 10 uF C83 4510002780 Electrolytic 16 SS 10 μF C84 4010000520 DD108 B 472K 50V Ceramic C85 4040000190 **Barrier Layer UAT 05X 103K** C86 4510002830 25 SS 4R7 μF Electrolytic C87 4510002830 Electrolytic 25 SS 4R7 µF 50 MS7 R47 μF CAR 4510001150 Electrolytic C89 4510002780 Electrolytic 16 SS 10 µF C90 4010000520 Ceramic DD108 B 472K 50V 50 RBP 1 μF C91 4510001740 Electrolytic C92 4510002730 Electrolytic 10 SS 100 μF C93 4510002780 Electrolytic 16 SS 10 μF

### [MAIN UNIT]

REF. NO.	ORDER NO.	D	ESCRIPTION
C94	4010000520	Ceramic	DD108 B 472K 50V
C95	4010000460	Ceramic	DD104 B 471K 50V
C96	4510002930	Electrolytic	50 SS R47 μF
C97	4510002940	Electrolytic	50 SS 1 μF
C98	4010000500	Ceramic	DD104 B 102K 50V
C99	4510002880	Electrolytic	25 SS 220 μF
C100	4510002640	Electrolytic	25 SS 47 μF
C101	4510002900	Electrolytic	25 SS 470 μF
C102	4510002640	Electrolytic	25 SS 47 μF
C103	4510002880	Electrolytic	25 SS 220 μF
C104	4040000260	Barrier Layer	UZE 08X 104M
C105	4510002830	Electrolytic	25 SS 4R7 μF
C106	4010000520	Ceramic	DD108 B 472K 50V
C107	4010000520	Ceramic	DD108 B 472K 50V
C108	4510002830	Electrolytic	25 SS 4R7 μF
C109	4510002830	Electrolytic	25 SS 4R7 μF
C110	4010000520	Ceramic	DD108 B 472K 50V
C111	4010000520	Ceramic	DD108 B 472K 50V
C113	4010000520	Ceramic	DD108 B 472K 50V
C115	4510002810	Electrolytic	16 SS 47 μF
C116	4040000260	Barrier Layer	UZE 08X 104M
C117	4010000500	Ceramic	DD104 B 102K 50V
C118	4510002830	Electrolytic	25 SS 4R7 μF
C119	4040000250	Barrier Layer	UAT 08X 473M
C120	4510002940	Electrolytic	50 SS 1 μF
C121	4040000150	Barrier Layer	UAT 05X 472K
C122	4510002900	Electrolytic	25 SS 470 μF
C123	4010000520	Ceramic	DD108 B 472K 50V
C124	4010000520	Ceramic	DD108 B 472K 50V
C125	4510002830	Electrolytic	25 SS 4R7 μF
C126	4040000260	Barrier Layer	UZE 08X 104M
C127	4040000260	Barrier Layer	UZE 08X 104M
C128	4040000260	Barrier Layer	UZE 08X 104M
C129	4510002910	Electrolytic Trimmer	25 SS 1000 μF CV38B 0601
C130 C131	4610000800 4040000190	Barrier Layer	UAT 05X 103K
C132	4510002850	Electrolytic	25 SS 22 uF
C132	4560000020	Ceramic	D33Y5V 1E 104Z21
C133	4510002830	Electrolytic	25 SS 4R7 μF
0134	4510002000	Liectronytro	20 00 4/11 μ1
S1	2220000300	Switch	SSSU12209B
SO1	6510008370	Socket	BBH-1
BT1	3020000110	Lithium Battery	CR2032
EP1	0910025354	P.C. Board	B 2458D (MAIN)

### [PLL UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
IC1	1120000970	ıc	M54562P
IC2	1190000020	IC	MC-5156
IC3	1140001280	IC	MB1501PF-G-BND
IC4	1110001970	IC	μPC1676G-T2

### [PLL UNIT]

REF. NO.	ORDER NO.		DESCRIPTION	REF. NO.	ORDER NO.		DESCRIPTION
IC5	1110001270	IC	BA6161M	L22	6180000900	Coil	LAL 03NA 101K
IC7	1790000050	l ic	ND487C1-3R	L27	6180000900	Coil	LAL 03NA 101K
IC8	1110001890	ıc	μPC1678G	L28	6180000960	Coil	LAL 03NA 102K
IC9	6910004320	IC	CB346M1B	L29	6140002060	Coil	LR-225
IC10	1110001890	IC	μPC1678G	L30	6140002060	Coil	LR-225
IC11	1120001700	IC	LA7910	L31	6200000260	Coil	LQN 2A R10K
				L32	6200000260	Coil	LQN 2A R10K
				L33	6150002750	Coil	LS-289
Q1	1530002360	Transistor	2SC2714-Y (TE85R)	L34	6150003050	Coil	LS-286
Q2	1530001950	Transistor	2SC2712-GR (TE85R)	L35	6200000150	Coil	NL 322522T-1R0M
Q3	1560000360	FET	2SK209-Y (TE85R)	L36	6200000150	Coil	NL 322522T-1R0M
Q5	1590000420	Transistor	RN1404 (TE85R)	L37	6110001530	Coil	LA-233 LA-233
Q6	1530002360	Transistor	2SC2714-Y (TE85R)	L38	6110001530	Coil Coil	LA-284
Q7	1510000580	Transistor	2SA1362-GR (TE85R)	L39	6110002140 6110002140	Coil	LA-384
Q8	1510000580	Transistor	2SA1362-GR (TE85R)	L40 L41	6200000150	Coil	NL 322522T-1R0M
Q9	1590000420	Transistor	RN1404 (TE85R)	L43	6110001990	Coil	LA-223
Q10	1590000420	Transistor	RN1404 (TE85R)	L44	6200000840	Coil	NL 322522T-R22M
Q11	1510000580	Transistor	2SA1362-GR (TE85R)	L45	6200000840	Coil	NL 322522T-R22M
Q12	1590000420 1520000180	Transistor Transistor	RN1404 (TE85R) 2SB798-T2 DL	L45	6910000670	Coil	BT01RN1-A61-001
Q13 Q14	1520000180	Transistor	25B798-12 DL RN1404 (TE85R)	L47	6910000670	Coil	BT01RN1-A61-001
Q14 Q15	1530002360	Transistor	2SC2714-Y (TE85R)	L47	6180000880	Coil	LAL 03NA 100K
Q16	1530002300	Transistor	2SC3772-3-TA	L49	6110001980	Coil	LA-222
Q10	1590002030	Transistor	RN1404 (TE85R)	L50	6110001980	Coil	LA-222
Q17	1390000420	Transistor	11111404 (12001)	L51	6110001980	Coil	LA-222
				L52	6200000720	Coil	LQN 2A 10NM
D1	1730002160	Zener	02CZ5.1-Z (TE85R)	L53	6110002010	Coil	LA-224
D2	1790000590	Diode	MA110 (TW)	L54	6110002010	Coil	LA-224
D3	1790000590	Diode	MA110 (TW)	L55	6150002750	Coil	LS-289
D4	1750000020	Diode	1SS184 (TE85R)	L56	6170000230	Coil	LW-25
D5	1790000590	Diode	MA110 (TW)	L57	6110001640	Coil	LA-247
D6	1790000590	Diode	MA110 (TW)				
D7	1790000590	Diode	MA110 (TW)				
D8	1790000590	Diode	MA110 (TW)	R1	7030000500	Resistor	MCR10EZHJ 10 kΩ (103)
D9	1790000590	Diode	MA110 (TW)	R3	7030000300	Resistor	MCR10EZHJ 220 Ω (221)
D10	1710000270	Diode	M1204	R4	7030000340	Resistor	MCR10EZHJ 470 Ω (471)
D11	1710000270	Diode	M1204	R5	7030000460	Resistor	MCR10EZHJ 4.7 kΩ (472)
D12	1710000270	Diode	MI204	R6	7030000500	Resistor	MCR10EZHJ 10 kΩ (103)
D13	1790000450	Diode	MA862 (TX)	R7	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
D14	1790000450	Diode	MA862 (TX)	R8	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
D15	1750000020	Diode	1SS184 (TE85R)	R9	7030000220	Resistor	MCR10EZHJ 47 Ω (470)
D17	1750000020	Diode	1SS184 (TE85R)	R10	7030000220	Resistor	MCR10EZHJ 47 $\Omega$ (470) MCR10EZHJ 270 $\Omega$ (271)
D18	1750000210	Diode	1SV237 (TE85R)	R12	7030000310	Resistor	MCR10EZHJ 15 Ω (150)
D21	1750000210	Diode	1SV237 (TE85R)	R13	7030000160	Resistor	MCR10EZHJ 270 Ω (271)
D22	1710000040	Diode	1S953	R14	7030000310	Resistor Resistor	MCR10EZHJ 10 kΩ (103)
D23	1750000020	Diode	1SS184 (TE85R) 1SS226 (TE85R)	R15 R16	7030000500	Resistor	R20J 1 kΩ
D24	1750000070	Diode	133220 (1E03N)	R17	7010004190	Resistor	R20J 1 kΩ
				R18	70300004190	Resistor	MCR10EZHJ 6.8 kΩ (682)
X1	6050006670	Crystal	CR-316	R19	7030000480	Resistor	MCR10EZHJ 1.2 kΩ (122)
^1	0030000070	Olystar	011-010	R20	7030000350	Resistor	MCR10EZHJ 560 Ω (561)
				R21	7010001170	Resistor	R25XJ 1.5 kΩ
L1	6180001220	Coil	LAL 04NA 100K	R22	7030000500	Resistor	MCR10EZHJ 10 kΩ (103)
L2	6200000150	Coil	NL 322522T-1R0M	R23	7030000260	Resistor	MCR10EZHJ 100 Ω (101)
L3	6200000880	Coil	NL 322522T-4R7M	R24	7030000390	Resistor	MCR10EZHJ 1.2 kΩ (122)
L4	6180002580	Coil	RCP095-472K-50	R25	7010004120	Resistor	R20J 270 Ω
L5	6180000960	Coil	LAL 03NA 102K	R26	7030000340	Resistor	MCR10EZHJ 470 Ω (471)
L6	6200000970	Coil	NL 322522T-100K	R27	7030000230	Resistor	MCR10EZHJ 56 Ω (560)
L7	6200000970	Coil	NL 322522T-100K	R28	7030000380	Resistor	MCR10EZHJ 1 kΩ (102)
L8	6200000970	Coil	NL 322522T-100K	R29	7030000260	Resistor	MCR10EZHJ 100 Ω (101)
L9	6200000970	Coil	NL 322522T-100K	R30	7030000260	Resistor	MCR10EZHJ 100 Ω (101)
L10	6200000970	Coil	NL 322522T-100K	R31	7030000260	Resistor	MCR10EZHJ 100 Ω (101)
L13	6180000960	Coil	LAL 03NA 102K	R32	7030000340	Resistor	MCR10EZHJ 470 Ω (471)
L14	6180000750	Coil	LAL 03NA R68M	R33	7030000310	Resistor	MCR10EZHJ 270 Ω (271)
	6180000960	Coil	LAL 03NA 102K	R34	7030000160	Resistor	MCR10EZHJ 15 Ω (150)
L15	0.0000000						
L15 L16	6180000960	Coil	LAL 03NA 102K	R35	7030000310	Resistor	MCR10EZHJ 270 Ω (271) R20J 100 Ω

### [PLL UNIT]

REF. NO.	ORDER NO.		DESCRIPTION	REF. NO.	ORDER NO.		DESCRIPTION
R37	7030000540	Resistor	MCR10EZHJ 22 kΩ (223)	C33	4510001100	Electrolytic	16 MS7 10 μF
R38	7030000300	Resistor	MCR10EZHJ 220 Ω (221)	C34	4030004720	Ceramic	C2012 JB 1H 102K- T-A
R39	7030000500	Resistor	MCR10EZHJ 10 kΩ (103)	C35	4510001100	Electrolytic	16 MS7 10 μF
R40	7030000500	Resistor	MCR10EZHJ 10 kΩ (103)	C36	4030004720	Ceramic	C2012 JB 1H 102K- T-A
R41	7030000420	Resistor	MCR10EZHJ 2.2 kΩ (222)	C37	4510001100	Electrolytic	16 MS7 10 μF C2012 JB 1H 102K- T-A
R42	7030000500	Resistor	MCR10EZHJ 10 kΩ (103)	C38	4030004720	Ceramic	16 MS7 10 μF
R43	7030000420	Resistor	MCR10EZHJ 2.2 kΩ (222)	C39	4510001100	Electrolytic Ceramic	C2012 JB 1H 102K- T-A
R44	7030000260	Resistor	MCR10EZHJ 100 Ω (101)	C40 C41	4030004720 4510001100	Electrolytic	16 MS7 10 μF
R45	7030000310	Resistor	MCR10EZHJ 270 Ω (271) MCR10EZHJ 270 Ω (271)	C41	4510001100	Electrolytic	50 SS 4R7 μF
R52	7030000310	Resistor	MCR10EZHJ 270 Ω (271) MCR10EZHJ 100 Ω (101)	C42	4510002970	Electrolytic	50 SS 4R7 μF
R53	7030000260 7030000280	Resistor Resistor	MCR10EZHJ 150 Ω (151)	C44	4510002800	Electrolytic	16 SS 33 μF
R55 R56	7030000280	Resistor	MCR10EZHJ 39 Ω (390)	C45	4030004760	Ceramic	C2012 JF 1E 104Z- T-A
R57	7030000210	Resistor	MCR10EZHJ 150 Ω (151)	C48	4030004760	Ceramic	C2012 JF 1E 104Z- T-A
R58	7030000500	Resistor	MCR10EZHJ 10 kΩ (103)	C49	4510000310	Electrolytic	16 MS16 1000 μF
R59	7030000420	Resistor	MCR10EZHJ 2.2 kΩ (222)				(12.5X16)
R60	7030000420	Resistor	MCR10EZHJ 2.2 kΩ (222)	C50	4510000310	Electrolytic	16 MS16 1000 μF
R61	7030000420	Resistor	MCR10EZHJ 2.2 kΩ (222)				(12.5X16)
R62	7010001280	Resistor	R25XJ 10 kΩ	C52	4030006450	Ceramic	C2012 JF 1H 103Z- T-A
R63	7030000260	Resistor	MCR10EZHJ 100 Ω (101)	C53	4030006450	Ceramic	C2012 JF 1H 103Z- T-A
R64	7030000320	Resistor	MCR10EZHJ 330 Ω (331)	C55	4030006450	Ceramic	C2012 JF 1H 103Z- T-A
R65	7030000230	Resistor	MCR10EZHJ 56 Ω (560)	C57	4030006450	Ceramic	C2012 JF 1H 103Z- T-A GRM40 SL 0R75C 50 PT
R66	7030000320	Resistor	MCR10EZHJ 330 Ω (331)	C58	4030003170	Ceramic	C2012 JB 1H 102K- T-A
R67	7030000260	Resistor	MCR10EZHJ 100 Ω (101)	C59	4030004720	Ceramic Electrolytic	16 SS 10 μF
R68	7030000300	Resistor	MCR10EZHJ 220 Ω (221)	C60 C62	4510002780 4030006450	Ceramic	C2012 JF 1H 103Z- T-A
R69	7030000540	Resistor	MCR10EZHJ 22 kΩ (223)	C62	4030004760	Ceramic	C2012 JF 1E 104Z- T-A
R70	7030000500	Resistor	MCR10EZHJ 10 kΩ (103) MCR10EZHJ 4.7 kΩ (472)	C64	4510001100	Electrolytic	16 MS7 10 μF
R71	7030000460	Resistor Resistor	MCR10EZHJ 1 kΩ (102)	C65	4030004760	Ceramic	C2012 JF 1E 104Z- T-A
R72 R73	731000380	Trimmer	EVN-2ACA00 B54 (503)	C71	4030004760	Ceramic	C2012 JF 1E 104Z- T-A
R74	70300003210	Resistor	MCR10EZHJ 270 Ω (271)	C79	4030008700	Ceramic	GRM40 B 473K 50PT
R75	7030000160	Resistor	MCR10EZHJ 15 Ω (150)	C85	4030008700	Ceramic	GRM40 B 473K 50PT
R76	7030000310	Resistor	MCR10EZHJ 270 Ω (271)	C92	4030004420	Ceramic	C2012 SL 1H 050C- T-A
R77	7030000260	Resistor	MCR10EZHJ 100 Ω (101)	C93	4030004420	Ceramic	C2012 SL 1H 050C- T-A
				C94	4030008700	Ceramic	GRM40 B 473K 50PT
	-			C95	4030004760	Ceramic	C2012 JF 1E 104Z- T-A
C1	4030006450	Ceramic	C2012 JF 1H 103Z- T-A	C96	4030004720	Ceramic	C2012 JB 1H 102K- T-A
C2	4030006450	Ceramic	C2012 JF 1H 103Z- T-A	C97	4030004560	Ceramic	C2012 SL 1H 390J- T-A
C3	4030006450	Ceramic	C2012 JF 1H 103Z- T-A	C98	4030004580	Ceramic	C2012 SL 1H 560J- T-A C2012 SL 1H 271J- T-A
C4	4030006450	Ceramic	C2012 JF 1H 103Z- T-A	C99	4030004670	Ceramic	C2012 SL 1H 2713- 1-A
C5	4030006450	Ceramic	C2012 JF 1H 103Z- T-A	C100	4030004380	Ceramic Ceramic	C2012 SL 1H 100D- T-A
C6	4030006450	Ceramic	C2012 JF 1H 103Z- T-A	C101	4030004470	1	C2012 SL 1H 270J- T-A
C7	4030006450	Ceramic	C2012 JF 1H 103Z- T-A	C102 C103	4030004530 4030004740	Ceramic Ceramic	C2012 JB 1H 472K- T-A
C8	4030006450	Ceramic	C2012 JF 1H 103Z- T-A	C103	4030004740	Ceramic	C2012 JB 1H 472K- T-A
C9	4510002780	Electrolytic	16 SS 10 μF C2012 JF 1H 103Z- T-A	C105	4030004140	Ceramic	C2012 JF 1H 103Z- T-A
C10	4030006450 4030001030	Ceramic Ceramic	GRM40 CH 151J 50P T	C106	4030003170	Ceramic	GRM40 SL 0R75C 50 PT
C11	4030001030	Ceramic	GRM40 CH 151J 50P T	C107	4030003170	Ceramic	GRM40 SL 0R75C 50 PT
C12 C13	4030001030	Ceramic	GRM40 SH 270J 50P T	C108	4030004710	Ceramic	C2012 JB 1H 471K- T-A
C14	4610000770	Trimmer	CV38D 1001	C109	4030004610	Ceramic	C2012 SL 1H 101J- T-A
C15	4030004520	Ceramic	C2012 SL 1H 220J- T-A	C110	4030004720	Ceramic	C2012 JB 1H 102K- T-A
C16	4030004610	Ceramic	C2012 SL 1H 101J- T-A	C111	4030004720	Ceramic	C2012 JB 1H 102K- T-A
C17	4030004720	Ceramic	C2012 JB 1H 102K- T-A	C113	4030004400	Ceramic	C2012 SL 1H 030C- T-A
C18	4030004610	Ceramic	C2012 SL 1H 101J- T-A	C114	4030004410	Ceramic	C2012 SL 1H 040C- T-A
C19	4030004720	Ceramic	C2012 JB 1H 102K- T-A	C115	4030004390	Ceramic	C2012 SL 1H 020C- T-A
C21	4030004720	Ceramic	C2012 JB 1H 102K- T-A	C116	4030004440	Ceramic	C2012 SL 1H 070D- T-A
C22	4510001100	Electrolytic	16 MS7 10 μF	C117	4030004390	Ceramic	C2012 SL 1H 020C- T-A
C23	4030004760	Ceramic	C2012 JF 1E 104Z- T-A	C118	4030004490	Ceramic	C2012 SL 1H 150J- T-A C2012 SL 1H 030C- T-A
C24	4030006450	Ceramic	C2012 JF 1H 103Z- T-A	C119	4030004400	Ceramic	
C25	4030004740	Ceramic	C2012 JB 1H 472K- T-A	C120	4030004720	Ceramic Ceramic	C2012 JB 1H 102K- T-A C2012 JB 1H 102K- T-A
C26	4030004720	Ceramic	C2012 JB 1H 102K- T-A	C121 C125	4030004720 4030004720	Ceramic	C2012 JB 1H 102K- T-A
C27	4560000110	Ceramic	D47X5T 1H 224M53	C125	4030004720	Ceramic	C2012 JB 1H 102K- T-A
C28	4030004740	Ceramic	C2012 JB 1H 472K- T-A	C126	4030004720	Ceramic	C2012 SL 1H 030C- T-A
C29	4510002630	Electrolytic	50 SS 47 μF C2012 JF 1E 104Z- T-A	C127	4030004480	Ceramic	C2012 SL 1H 010C- T-A
C30	4030004760	Ceramic	C2012 JF 1E 104Z- 1-A	C128	4030004350	Ceramic	C2012 SL 1H 080D- T-A
C24	10300014700						
C31 C32	4030004720 4030004720	Ceramic Ceramic	C2012 JB 1H 102K- T-A	C130	4030004380	Ceramic	C2012 SL 1H 010C- T-A

### [PLL UNIT]

### REE **ORDER** DESCRIPTION NO. NO. C131 4030004480 Ceramic C2012 SL 1H 120J- T-A 4030004400 C2012 SL 1H 030C- T-A C132 Ceramic C134 4030004720 Ceramic C2012 JB 1H 102K- T-A C135 4030004720 Ceramic C2012 JB 1H 102K- T-A C2012 SL 1H 101J- T-A C137 4030004610 Ceramic C138 4030004720 Ceramic C2012 JB 1H 102K- T-A C139 4030004710 Ceramic C2012 JB 1H 471K- T-A C140 4030004710 Ceramic C2012 JB 1H 471K- T-A C2012 JB 1H 102K- T-A 4030004720 Ceramic C147 C148 4030004400 Ceramic C2012 SL 1H 030C- T-A C2012 SL 1H 070D- T-A C149 4030004440 Ceramic C150 4030004430 Ceramic C2012 SL 1H 060D- T-A C154 4030004400 Ceramic C2012 SL 1H 030C- T-A C155 4030004370 Ceramic C2012 SL 1H 0R5C- T-A 4030004380 C2012 SL 1H 010C- T-A C156 Ceramic C157 4030004720 Ceramic C2012 JB 1H 102K- T-A C158 4030004720 Ceramic C2012 JB 1H 102K- T-A C2012 JB 1H 102K- T-A C159 4030004720 Ceramic C160 4510001190 Electrolytic 50 MS7 4R7 μF C161 4030004720 Ceramic C2012 JB 1H 102K- T-A C2012 JB 1H 102K- T-A 4030004720 Ceramic C162 C163 4030004720 Ceramic C2012 JB 1H 102K- T-A C2012 JF 1E 104Z- T-A C164 4030004760 Ceramic 10 SS 47 μF C165 4510002720 Electrolytic C166 4030004400 Ceramic C2012 SL 1H 030C- T-A C167 4030004400 Ceramic C2012 SL 1H 030C- T-A C2012 JF 1E 104Z- T-A C168 4030004760 Ceramic C169 4030004760 Ceramic C2012 JF 1E 104Z- T-A C170 4030003170 Ceramic GRM40 SL 0R75C 50 PT GRM40 SL 0R75C 50 PT C171 4030003170 Ceramic C172 4030004570 Ceramic C2012 SL 1H 470J- T-A C2012 JF 1H 103Z- T-A C173 4030006450 Ceramic 4030004470 C2012 SL 1H 100D- T-A C174 Ceramic C175 4030004740 Ceramic C2012 JB 1H 472K- T-A C176 4030003170 Ceramic GRM40 SL 0R75C 50 PT 4030004720 C2012 JB 1H 102K- T-A C177 Ceramic 4030001030 Ceramic GRM40 CH 151J 50P T C178 C179 4030004710 Ceramic C2012 JB 1H 471K- T-A C180 4030004720 Ceramic C2012 JB 1H 102K- T-A C181 4510003040 Electrolytic 16 SS 100 µF C182 4030004720 Ceramic C2012 JB 1H 102K- T-A C184 4550000890 **Tantalum** TESVC 1C 475M-12L C185 4030004460 Ceramic C2012 SL 1H 090D- T-A RL<sub>1</sub> 6330000810 **ARK115** Relay RL2 6330000810 Relay **ARK115** RL3 6330000810 **ARK115** Relay RL4 6330000810 Relay **ARK115** RL5 6330000810 Relay **ARK115** FP1 0910025594 P.C. Board B 2459D (PLL) EP2 6910003430 Lead Frame VTYA 6U80J EP3 0910026610 P.C. Board B 2695 (PLL) **Downloaded by** □ Amateur Radio Directory ☐ www.hamdirectory.info

### [FIL 1 UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
L1	6200000880 6200000880	Coil	NL 322522T-4R7M NL 322522T-4R7M
4	020000000	0011	NE OZZOZZI TIVIN
C1	4030004720	Ceramic	C2012 JB 1H 102K- T-A
C2	4030004720	Ceramic	C2012 JB 1H 102K- T-A
C3	4030004710	Ceramic	C2012 JB 1H 471K- T-A
C4	4030004690	Ceramic	C2012 SL 1H 331J- T-A
C5	4030004710	Ceramic	C2012 JB 1H 471K- T-A
EP1	0910025500	P.C. Board	B 2598 (FIL 1)
EP2	6910002720	Lead Frame	HFB2.54-0.9-8 (N)

### [FIL 2 UNIT]

L1 L2	6200000980	Coil	NL 322522T-8R2M
L2	000000000		ITE OLLOLLI OI ILIN
	6200000880	Coil	NL 322522T-4R7M
C1	4030004730	Ceramic	C2012 JB 1H 222K- T-A
C2	4030004720	Ceramic	C2012 JB 1H 102K- T-A
С3	4030004730	Ceramic	C2012 JB 1H 222K- T-A
C4	4030004710	Ceramic	C2012 JB 1H 471K- T-A
C5	4030004710	Ceramic	C2012 JB 1H 471K- T-A
C6	4030006450	Ceramic	C2012 JF 1H 103Z- T-A
C7	4030004730	Ceramic	C2012 JB 1H 222K- T-A
C8	4030004720	Ceramic	C2012 JB 1H 102K- T-A
EP1	0910025511	P.C. Board	B 2599A (FIL 2)
EP2	6910002720	Lead Frame	HFB2.54-0.9-8 (N)

### [FIL 3 UNIT]

REF. NO.	ORDER NO.	DESCRIPTION			
L1	6200000950	Coil	NL 322522T-R18M		
L2	6200000940	Coil	NL 322522T-R27M		
C1	4030004580	Ceramic	C2012 SL 1H 560J- T-A		
C2	4030004610	Ceramic	C2012 SL 1H 101J- T-A		
C3	4030004620	Ceramic	C2012 SL 1H 121J- T-A		
C4	4030004520	Ceramic	C2012 SL 1H 220J- T-A		
C5	4030004600	Ceramic	C2012 SL 1H 820J- T-A		
EP1	0910025520	P.C. Board	B 2600 (FIL 3)		
EP2	6910002720	Lead Frame	HFB2.54-0.9-8 (N)		

**IFIL 4 UNIT1** 

FIL 4	נוואט		
REF. NO.	ORDER NO.		DESCRIPTION
L1	6200000950	Coil	NL 322522T-R18M
L2	6200000840	Coil	NL 322522T-R22M
L3	6200000960	Coil	NL 322522T-R33M
L4	6200000840	Coil	NL 322522T-R22M
C1	4030004600	Ceramic	C2012 SL 1H 820J- T-A
C2	4030004500	Ceramic	C2012 SL 1H 180J- T-A C2012 SL 1H 560J- T-A
C3	4030004580 4030004630	Ceramic Ceramic	C2012 SL 1H 151J- T-A
C4 C5	4030004670	Ceramic	C2012 SL 1H 271J- T-A
C6	4030004600	Ceramic	C2012 SL 1H 820J- T-A
C7	4030004710	Ceramic	C2012 JB 1H 471K- T-A
C8	4030004690	Ceramic	C2012 SL 1H 331J- T-A
C9	4030004630	Ceramic	C2012 SL 1H 151J- T-A
EP1 EP2	0910025530 6910002720	P.C. Board Lead Frame	B 2601 (FIL 4) HFB2.54-0.9-8 (N)
		The second secon	
	<u> </u>	<u> </u>	

# SECTION 7 ADJUSTMENT PROCEDURES

### 7-1 PREPARATION BEFORE SERVICING

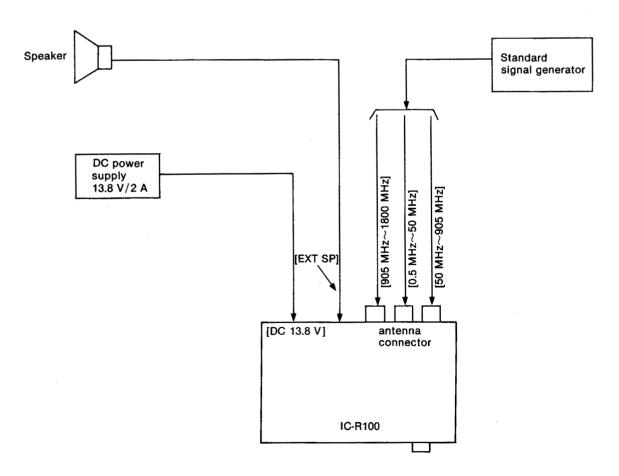
### **■ REQUIRED TEST EQUIPMENT**

EQUIPMENT	GRADE AND RANGE	EQUIPMENT	GRADE AND RANGE
DC power supply	Output voltage : 13.8 V DC Current capacity : 2 A or more	Oscilloscope	Frequency range : DC~50 MHz Measuring range : 0.01~10 V
Frequency counter	Frequency range : 0.1 MHz~1 GHz	Digital DC voltmeter	Input impedance : 10 $M\Omega/DC$ or better
	Frequency accuracy: ±1 ppm or better Sensitivity: 100 mV or better	Standard signal generator (SSG)	Frequency range : 0.1 MHz~2 GHz Output level : -127~-17 dBm
RF voltmeter	Frequency range : 0.1~500 MHz Measuring range : 0.01~10 V	- generator (33d)	(0.1 μV~32 mV)

CW: Clockwise

CCW: Counterclockwise

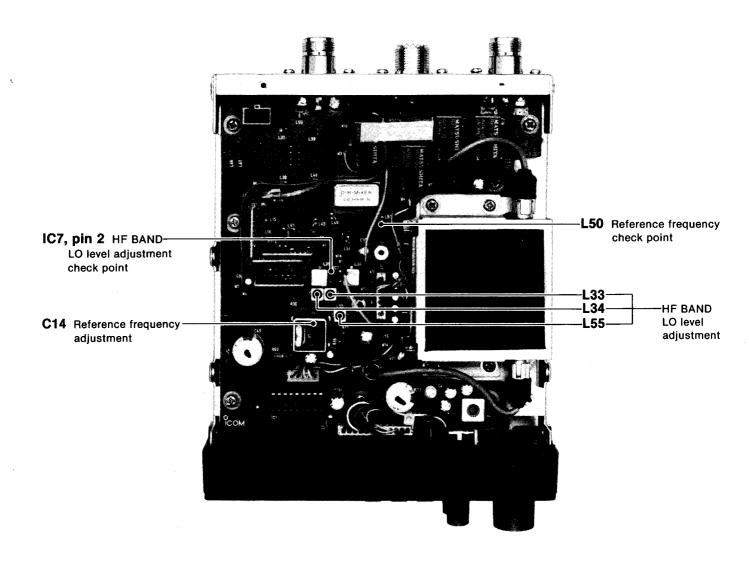
### 7-2 TEST EQUIPMENT CONNECTION



### 7-3 PLL ADJUSTMENT

AD MOTHENT		AD WATER TO AND TIONS	N	IEASUREMENT	VALUE	ADJUSTMENT POINT	
ADJUSTME	NT	ADJUSTMENT CONDITIONS	UNIT	LOCATION	VALUE	UNIT	ADJUST
REFERENCE FREQUENCY	1	Displayed frequency:     1300.000 MHz (FRG version)     1856.000 MHz     (All other versions)     Mode : FM	PLL	Connect the frequency counter to L50.	673.000 MHz (FRG) 951.000 MHz (All other versions)	PLL	C14
HF BAND LO LEVEL	1	Displayed frequency: 28.000 MHz     Mode : FM	PLL	Connect the RF voltmeter to IC7, pin 2.	Maximum level (more than 170 mVrms)	PLL	Adjust in sequence L55, L34, L33

### • PLL UNIT

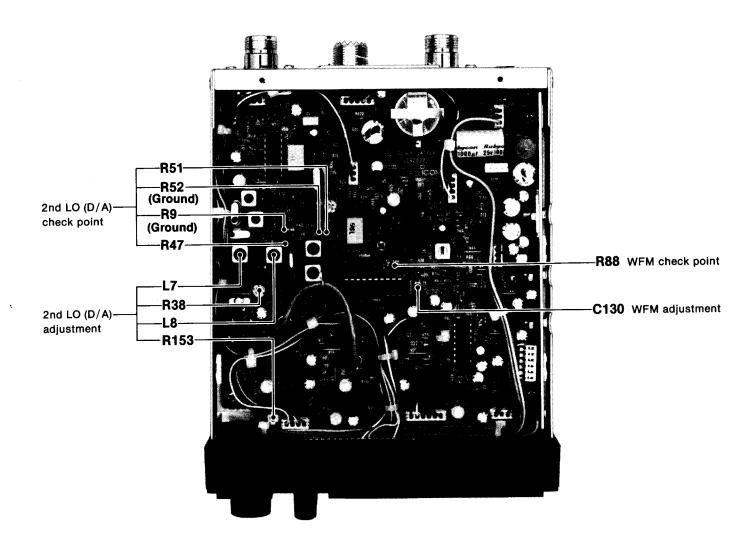


### 7-4 RECEIVER ADJUSTMENT

ADJUSTMENT		ADJUSTMENT CONDITIONS	MEASUREMENT		VALUE	ADJUSTMENT POINT	
			UNIT LOCATION	UNIT		ADJUST	
2nd LO (D/A)	1	Displayed frequency:     144.100 MHz (FRG version)     120.100 MHz (All other versions)     Mode : FM	MAIN	Connect the frequency counter to R51 and R52 (GND).	Preset to center.	MAIN	R38, R153
	2				35.3000 MHz		R38
	3			Connect the RF voltmeter to R47 and R9 (GND).	Maximum level (More than 300 mVrms)		L7, L8
	4	Displayed frequency:     144.105 MHz (FRG version)     120.105 MHz (All other versions)     Mode : FM     Remove RF voltmeter.		Connect the frequency counter to R51 and R52 (GND).	35.2950 MHz		R153
	5	Displayed frequency:     144.100 MHz (FRG version)     120.100 MHz (All other versions)     Mode : FM			35.3000 MHz		R38
	6	Repeat steps 4 and 5 several times.					
WFM	1	• Displayed frequency: 144.100 MHz (FRG version) 120.100 MHz (All other versions) • Mode : WFM • [PRE/ATT] switch : OFF • Set the signal generator; Level : 3.2 μV* (−97 dBm) Modulation: 1 kHz Deviation : 50 kHz	MAIN	Connect the digital DC voltmeter to R88.	2.5 V	MAIN	C130

<sup>\*</sup>This output level of the standard signal generator (SSG) is indicated as SSG's open circuit.

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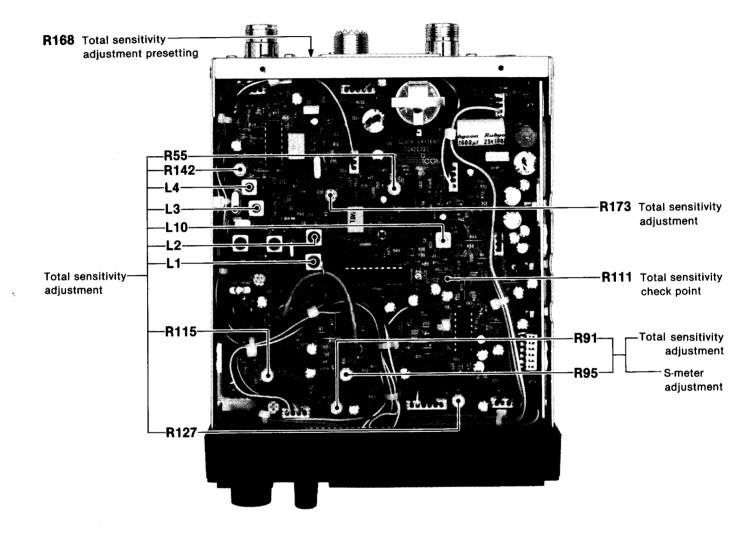


### RECEIVER ADJUSTMENT (CONTINUED)

ADJUSTMENT		ADJUSTMENT CONDITIONS	MEASUREMENT		VALUE	ADJUSTMENT POINT	
			UNIT	LOCATION	VALUE	UNIT	ADJUST
TOTAL SENSITIVITY	1	Displayed frequency:     144.100 MHz (FRG version)     120.100 MHz (All other versions)     Mode: FM     [PRE/ATT] switch: OFF     R168 (MAIN): Max. CW	MAIN	Connect the digital DC voltmeter to R111.	Preset to center.	MAIN	R142, R95, R91, R55, R115, R127
	2	• Set the signal generator; Level : 10~320 µV* (-87~-57 dBm) Modulation: 1 kHz Deviation : 5.0 kHz			Minimum		Adjust in sequence L1~L4, L10
	3	• Set the signal generator; Level : 3.2~32 μV* (-97~-77 dBm) Modulation: 1 kHz Deviation : 10.0 kHz			Minimum		Adjust in sequence L1, L2
τ.	4	• Set the signal generator; Level : 3.2 µV* (-97 dBm) Modulation: 1 kHz Deviation : 5.0 kHz					Adjust in sequence L3, L4, L10
	5	Repeat steps 3 and 4 several times.	<u> </u>				
	6	Set the signal generator;     Level : 1 μV* (-107 dBm)     Modulation: OFF			5.9 V		R142
	7	• Mode : AM					R173
S-METER	1	Displayed frequency:  144.100 MHz (FRG version)  120.100 MHz (All other versions)  Mode : FM  [PRE/ATT] switch : OFF  Set the signal generator;  Level : 3.2 µV* (-97 dBm)  Modulation: OFF	Function display	S indicator	3 dots (S5)	MAIN	R95
	2	• Mode : AM					Verify
	3	Displayed frequency:  144.100 MHz (FRG version)  87.000 MHz (All other versions)  Mode: WFM Set the signal generator;  Level: 3.2 µV* (-97 dBm)  Modulation: OFF			3 dots (S3)	-	R91

<sup>\*</sup>This output level of the standard signal generator (SSG) is indicated as SSG's open circuit.

### • MAIN UNIT

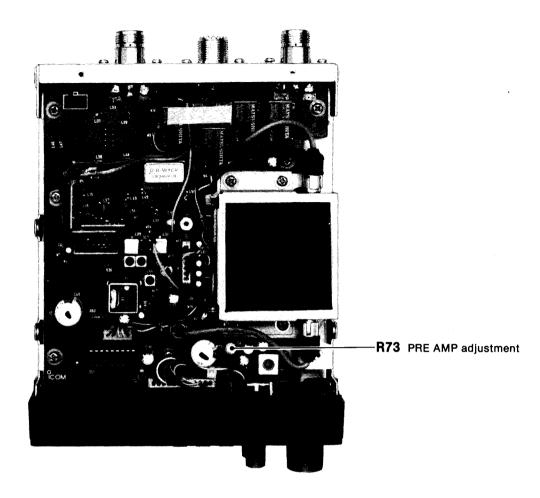


### RECEIVER ADJUSTMENT (CONTINUED)

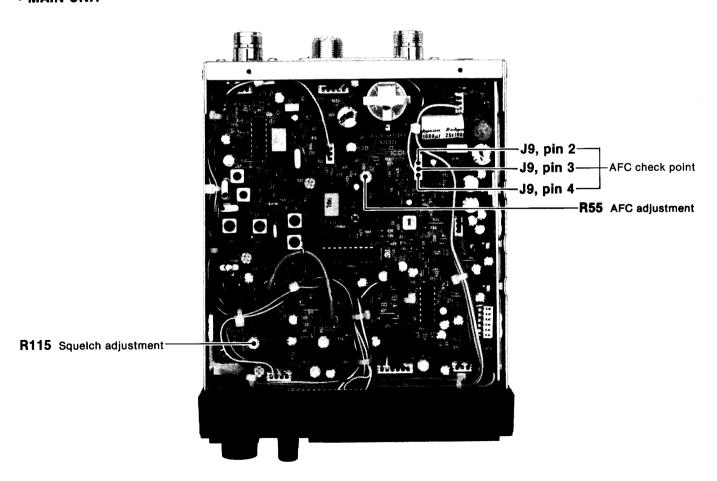
ADJUSTMENT		ADJUSTMENT CONDITIONS	MEASUREMENT		VALUE	ADJUSTMENT POINT	
			UNIT	LOCATION	VALUE	UNIT	ADJUST
PRE AMP	1	Displayed frequency:  144.100 MHz (FRG version)  120.100 MHz (All other versions)  Mode : FM  [PRE/ATT] switch : ON  Set the signal generator;  Level : 1.8 µV* (-102 dBm)  Modulation: OFF	Function display	S indicator	3 dots (S5)	PLL	R73
AFC	1	Displayed frequency:  144.100 MHz (FRG version)  120.100 MHz (All other versions)  Mode : FM  [PRE/ATT] switch : OFF  Set the signal generator;  Level : 3.2 µV* (-97 dBm)  Modulation: OFF	MAIN	Connect the oscilloscope to J9, pin 3.	0 V	MAIN	R55
	2	Shift the signal generator frequency: ±2 kHz					
	3	Shift the signal generator frequency: +5 kHz		Connect the oscilloscope to J9, pin 4.			Verify
	4	Shift the signal generator frequency: -5 kHz		Connect the oscilloscope to J9, pin 2.			
SQUELCH	1	Displayed frequency:     144.100 MHz (FRG version)     120.100 MHz (All other versions)     Mode : FM     [PRE/ATT] switch : OFF     Apply no signal to the antenna connector.	Bottom cover	Speaker	Squelch threshold point is between the 9 o'clock and 11 o'clock.	Front panel	[SQUELCH] control
	2	• Mode : AM			Same position as FM mode.	MAIN	R115
	3	• Mode : WFM					Verify

<sup>\*</sup>This output level of the standard signal generator (SSG) is indicated as SSG's open circuit.

### • PLL UNIT



### • MAIN UNIT



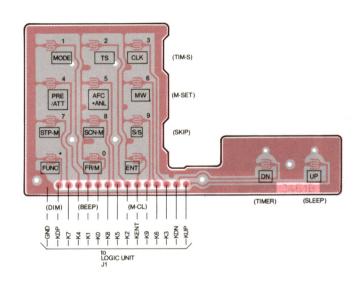
# **SECTION 8**

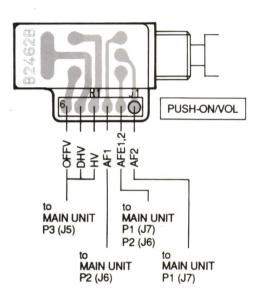
## **BOARD LAYOUTS**

### 8-1 SUBORDINATE LOGIC UNITS

### • TENKEY UNIT

### VR UNIT







(Symbol: B3)



**1SS187** (Symbol: D3)

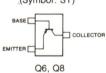


**1SS190** (Symbol: E3)



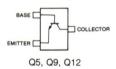
2SA1162 Y

(Symbol: SY)

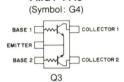


2SC2712 Y

(Symbol: LY)

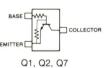


FMG4 T148



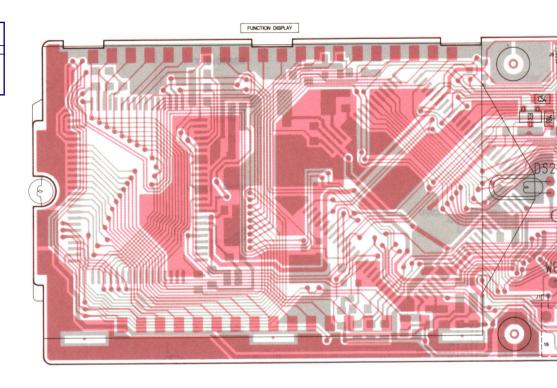
RN1404

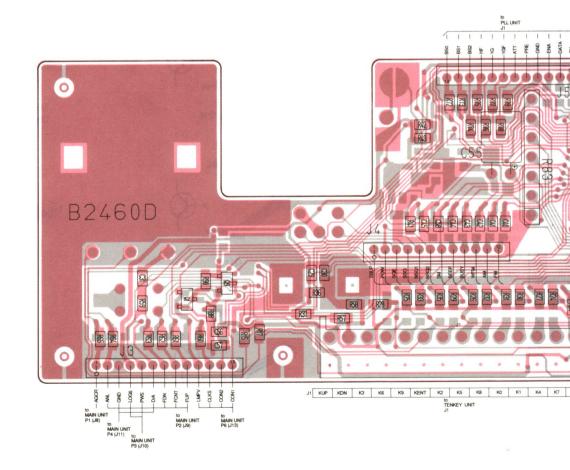
(Symbol: XD)

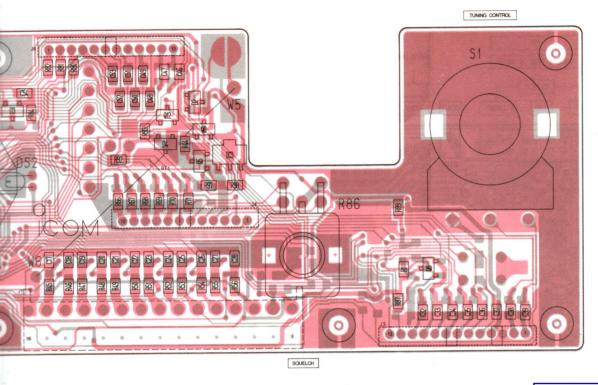


### • LOGIC UNIT

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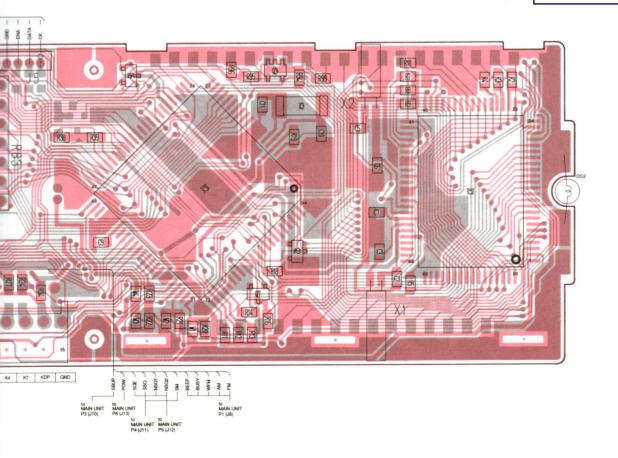




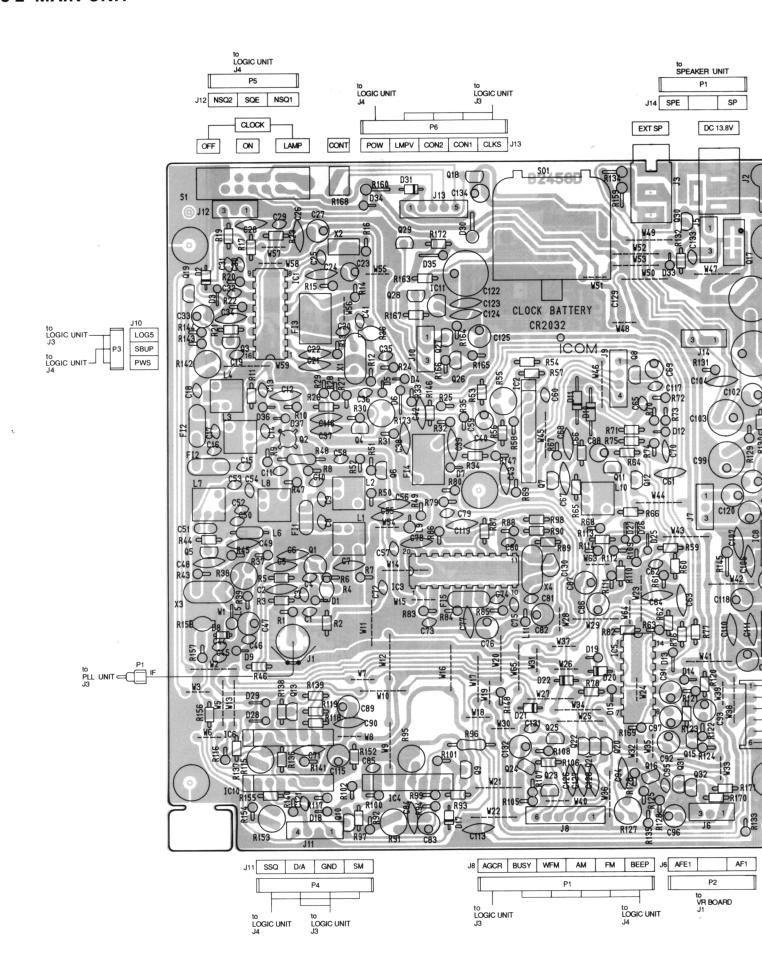


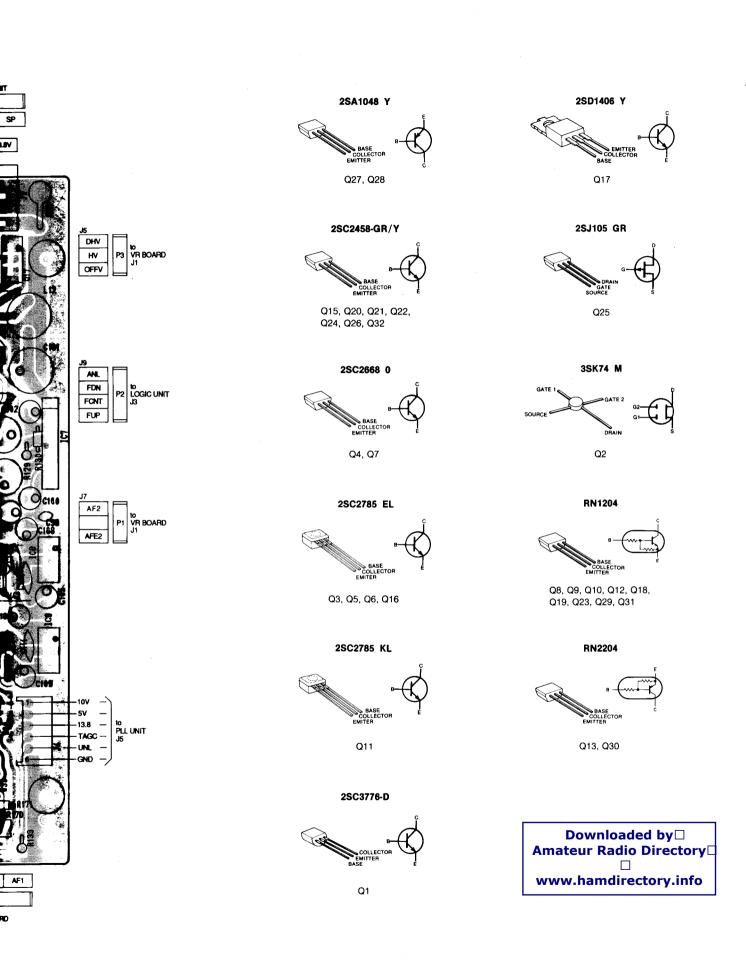
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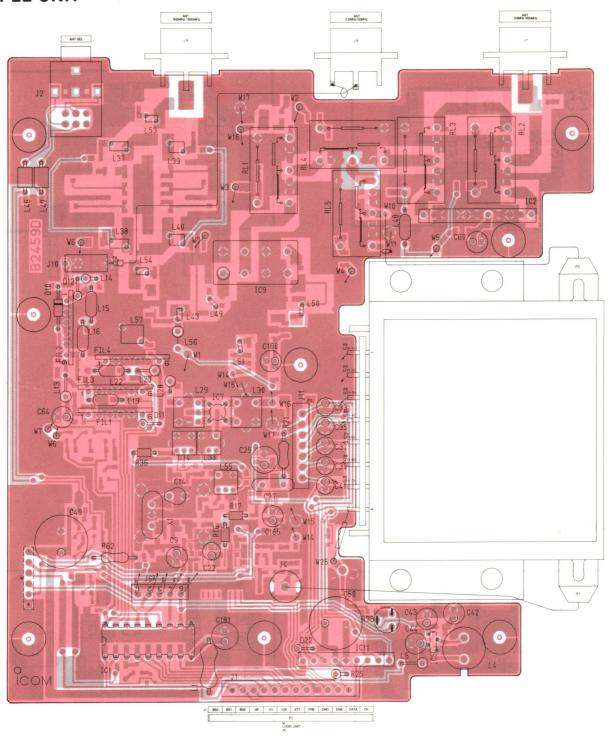


### 8-2 MAIN UNIT





### 8-3 PLL UNIT







**1SS184** (Symbol: B3)



D4, D15, D17, D23

**1SS226** (Symbol: C3)

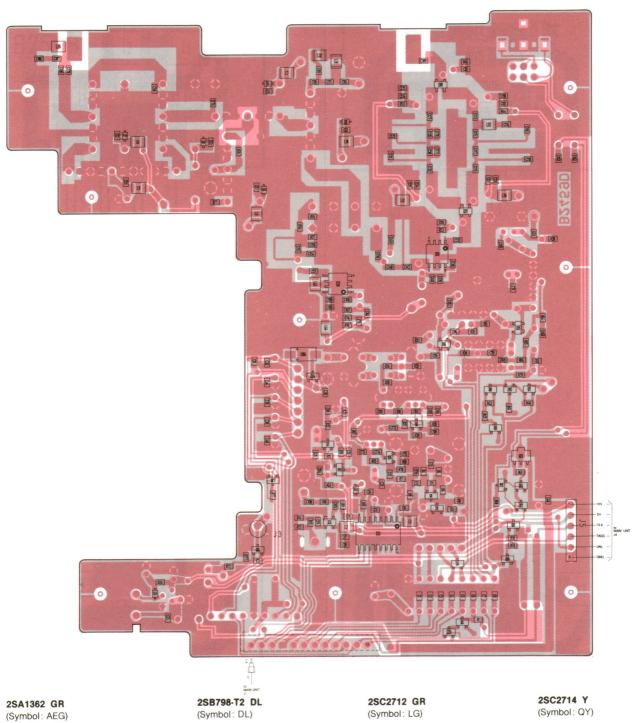


D24

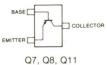
MA862 (Symbol: M1I)



D13, D14







BASE 🗖 EMITTER Q13

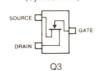
(Symbol: LG) EMITTER [ Q2

COLLECTOR EMITTER Q1, Q6, Q15

#### 2SC3772 3 (Symbol: LY3)

BASE [ Q16

#### 2SK209 Y (Symbol: XY)

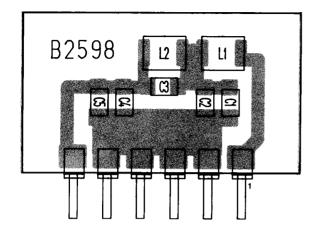


# RN1404 (Symbol: XD)

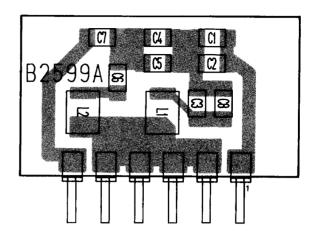
Q5, Q9, Q10, Q12, Q14, Q17

### **8-4 SUBORDINATE PLL UNITS**

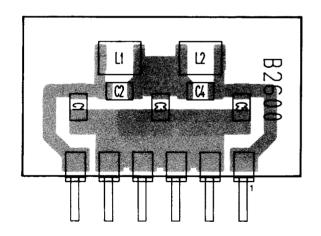
#### • FIL 1 UNIT



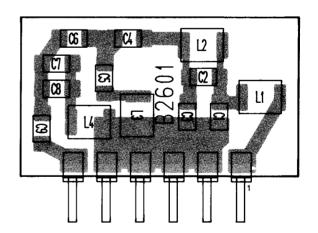
### • FIL 2 UNIT



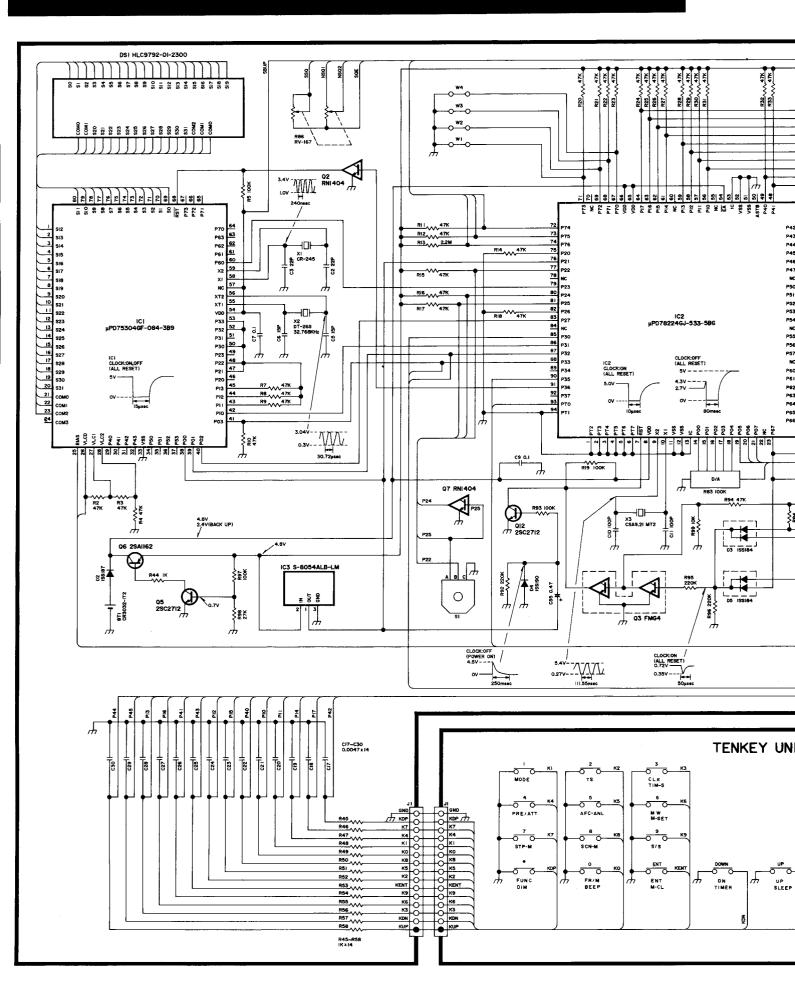
#### • FIL 3 UNIT



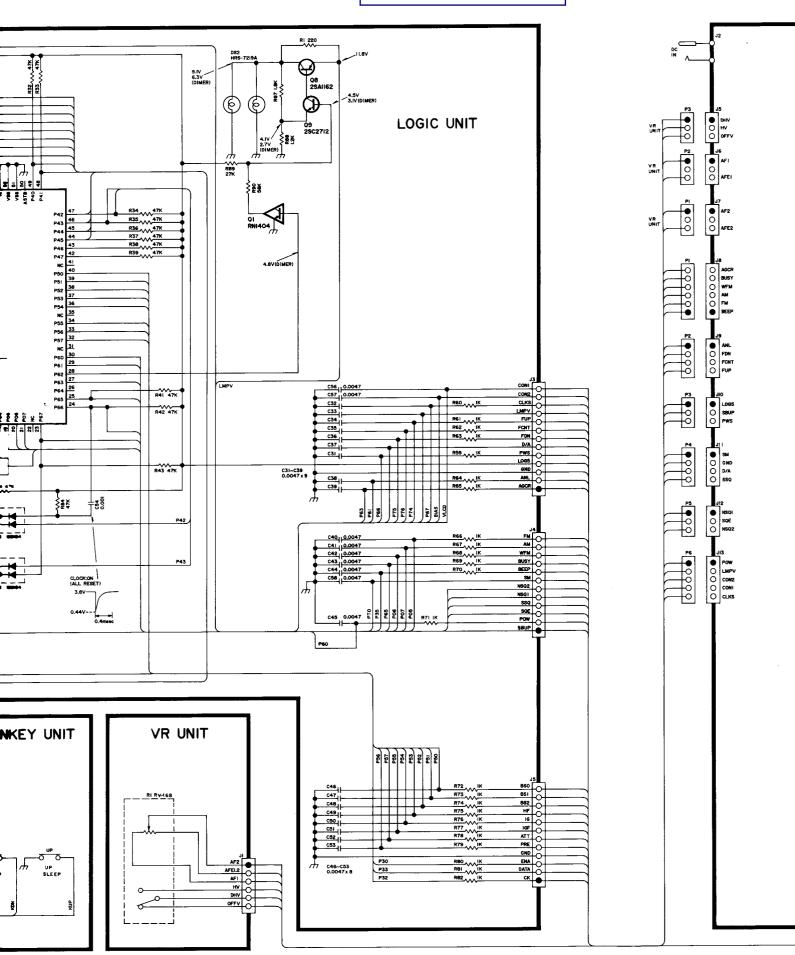
#### • FIL 4 UNIT

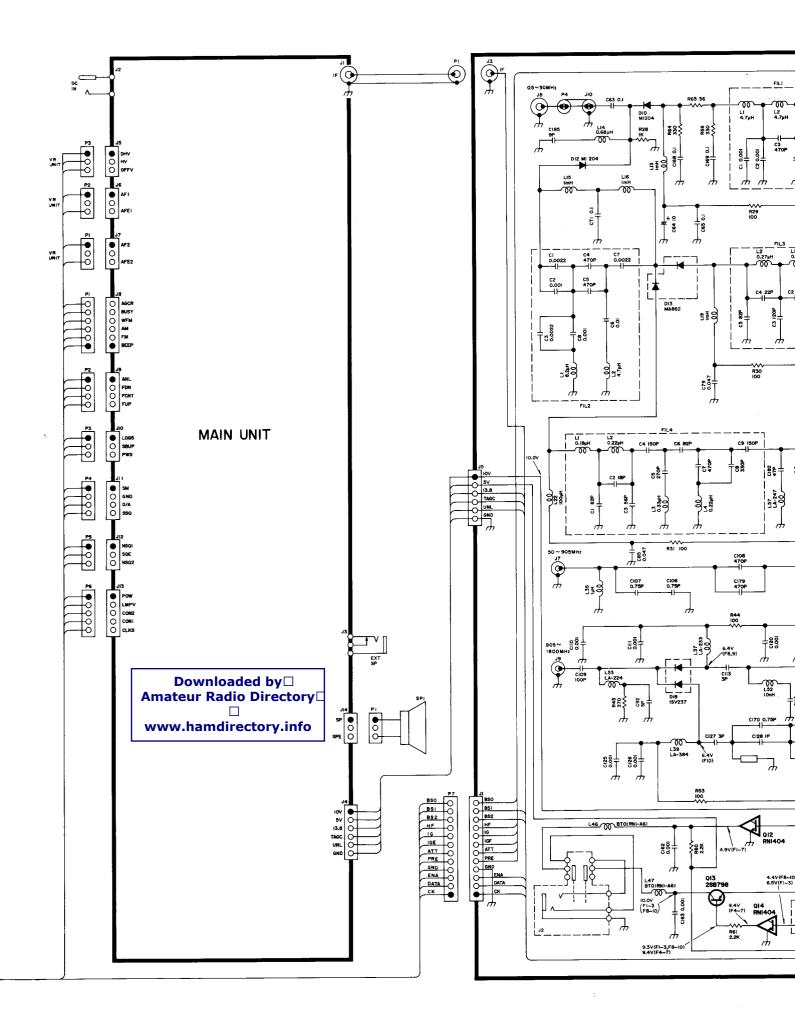


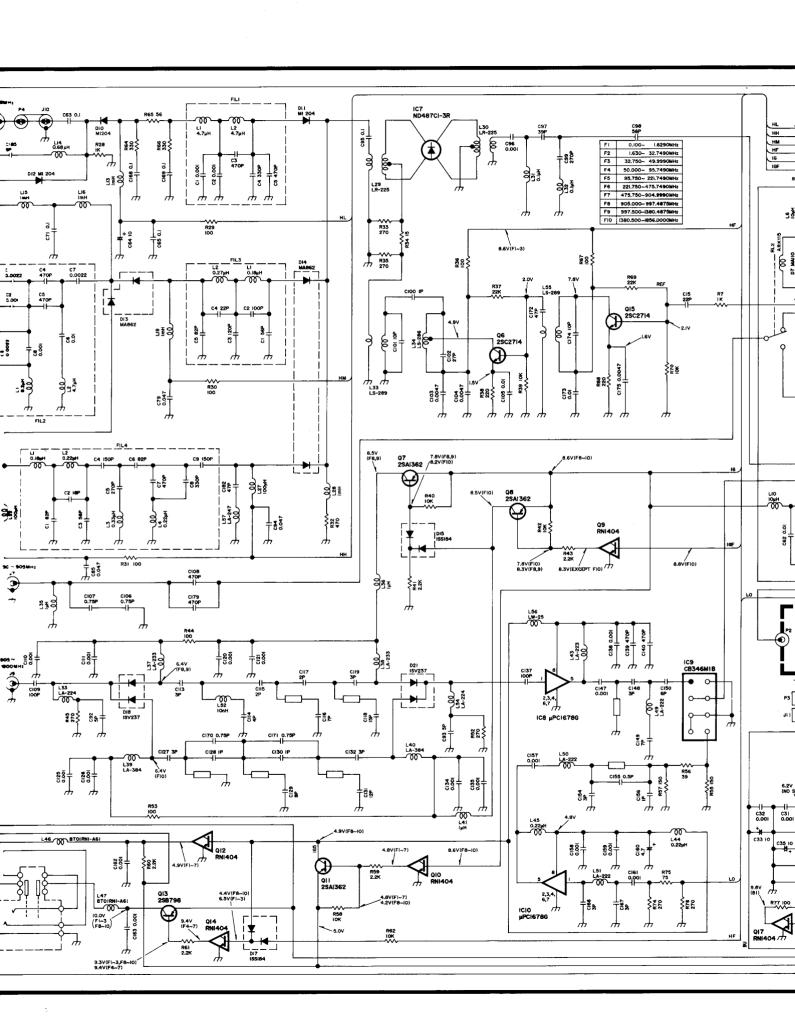
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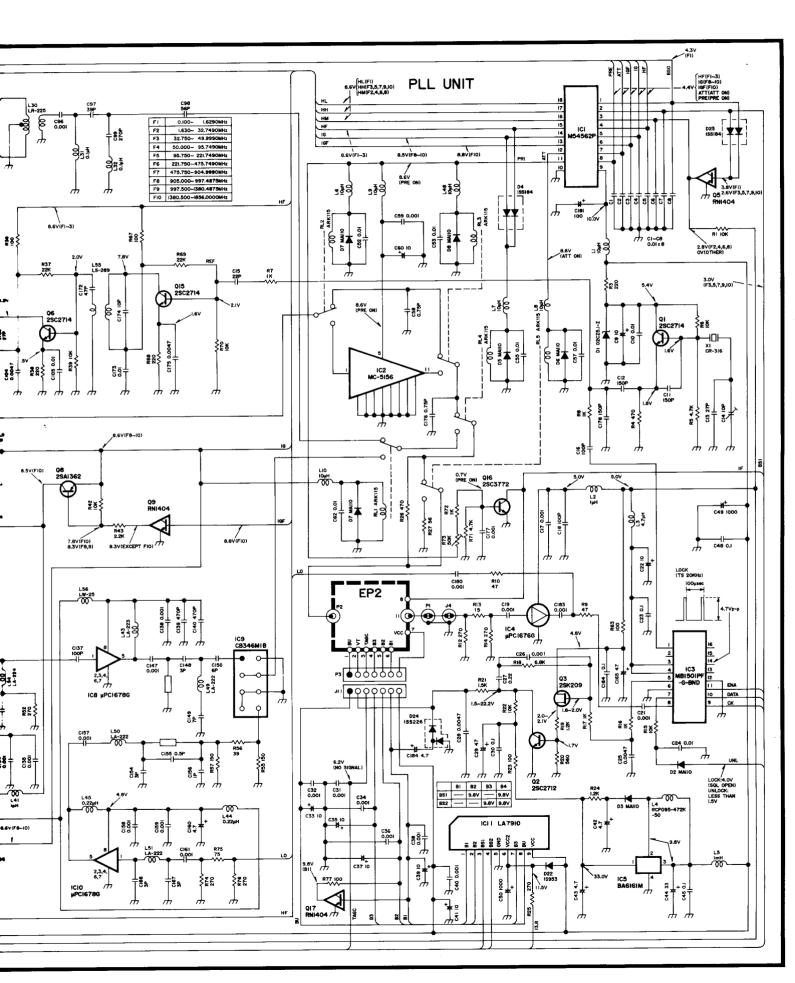


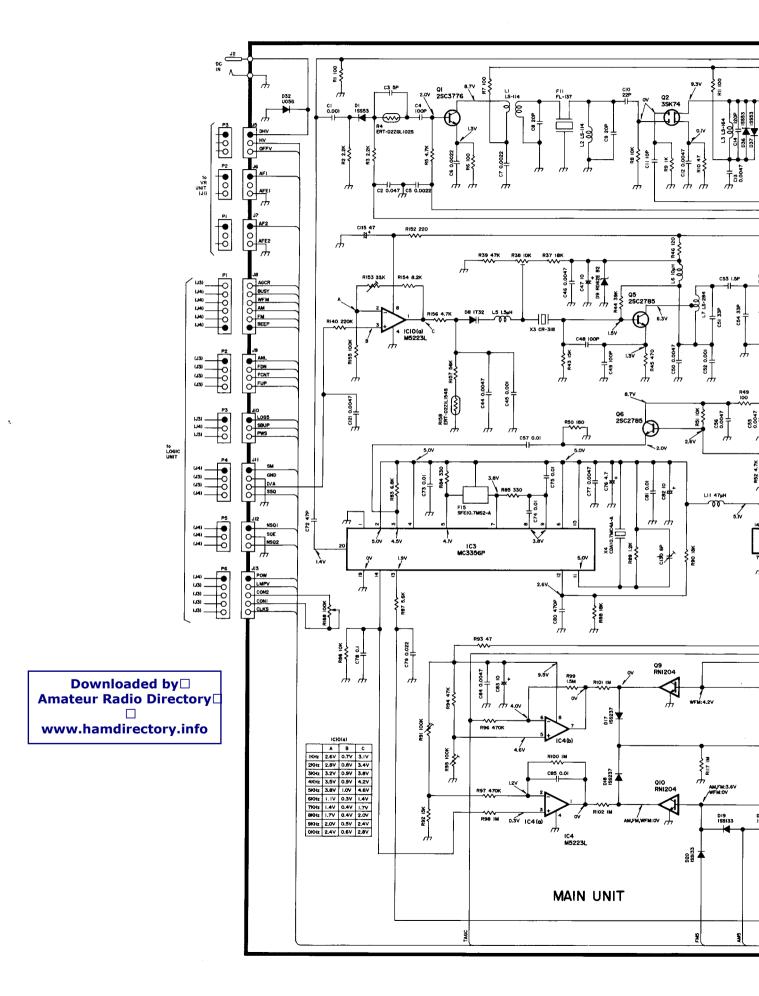
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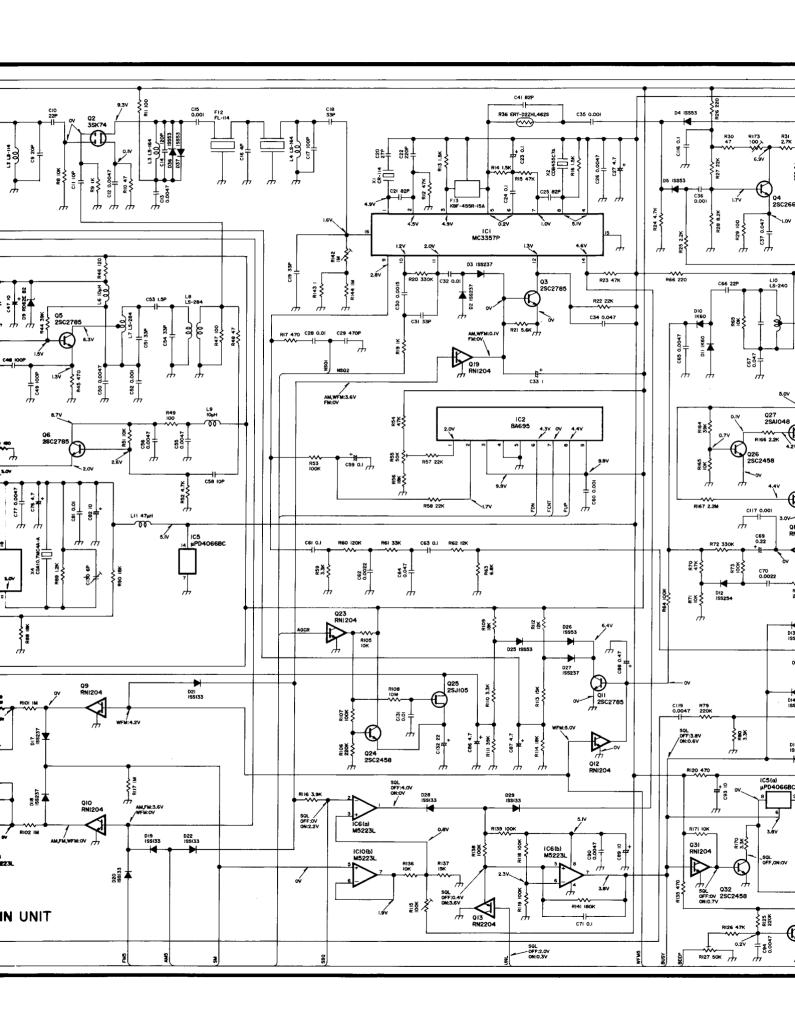


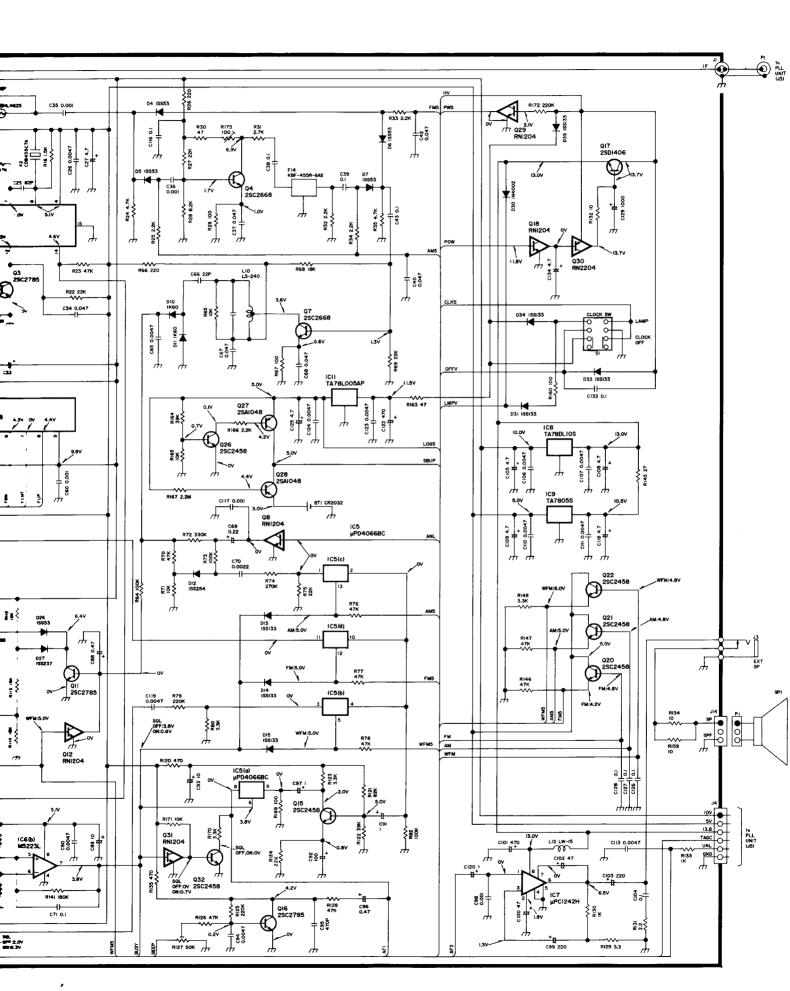












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